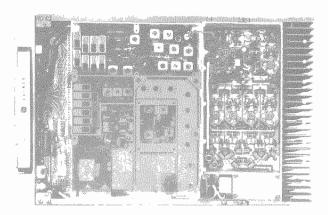
(Supersedes LBI4600)

# MASTR II AINTENANCE MANUAL

25-50 MHz, 100-WATT TRANSMITTER



# SPECIFICATIONS \*

Frequency Range

Power Output

Crystal Multiplication Factor

Frequency Stability 5C-ICOM with EC-ICOM 5C-ICOM or EC-ICOM 2C-ICOMS

Spurious and Harmonic Emission

Modulation

Modulation Sensitivity

Audio Frequency Characteristics

Distortion

Deviation Symmetry

Duty Cycle

Maximum Frequency Spread: (2 to 8 channels)

> 30-36 MHz 36-42 MHz. 42-50 MHz

25-50 MHz

100 Watts (Adjustable from 50 to 100 Watts at 30 to 50 MHz, and from 75 to 100 Watts at 25 to 30 MHz)

 $\pm 0.0005\%$  (-40°C to  $\pm 70$ °C) t0,0002% (0°C to +55°C) t0.0002% (-40°C to +70°C)

At least 85 dB below full rated power output

Adjustable from 0 to ±5 kHz swing with instantaneous modulation limiting.

80 to 120 Villivolts

Within +1 dB to -3 dB of a 6-dB/octave preemphasis from 300 to 3000 Hz per EIA standards. Post limiter filter per FCC and EIA.

Less than 2% (1000 Hz) Less than 3% (300 to 3000 Hz)

0.5 kHz maximum

EIA 20% Intermittent

Full Specifications I dB Degradation

.320 MHz .LGO MHz .200 MHz .400 MHz .240 MHz .470 MHz .280 MHz ,540 MHz

<sup>\*</sup>These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications

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#### -- WARNING --

Although the highest DC voltage in MASTR II Vobile Equipment is supplied by the vehicle battery, high currents may be drawn under short circuit conditions. These currents can possibly heat metal objects such as tools, rings, watchbands, etc., enough to cause burns. Be careful when working near energized circuits!

High-level RF energy in the transmitter power Amplifier assembly can cause RF burns upon contact. KEEP AWAY FROM THESE CIRCUITS WHEN THE TRANSMITTER IS ENERGIZED!

#### DESCRIPTION

MASTR II transmitters are crystal-controlled phase modulated and designed for one-through eight-frequency operation in the 25 to 50 megahertz band. The solid state transmitter utilizes both integrated circuits (ICs) and discrete components, and consists of the following assemblies:

- Exciter Board; with audio, modulator, amplifier and multiplier stages.
- Power Amplifier Assembly; with amplifier, driver, PA, power control, filter and antenna switch.

#### CIRCUIT ANALYSIS

#### **EXCITER**

The exciter uses nine transistors and two integrated circuits to drive the PA assembly. The exciter can be equipped with up to eight Integrated Circuit Oscillator Modules (ICOMs). The ICOM crystal frequency ranges from approximately 8.33 to 16.67 megahertz, and the crystal frequency is multiplied three times (divided by four

and multiplied by 12 for a multiplication factor of three).

Audio, supply voltages and control functions are connected from the system board to the exciter board through P902.

Centralized metering jack J103 is provided for use with GE Test Set Model 4EX3All or Test Kit 4EX8K12. The test set meters the modulator, multiplier and amplifier stages.

#### ICOMS

Three different types of ICOMs are available for use in the exciter. Each of the ICOMs contains a crystal-controlled Colpitts oscillator, and two of the ICOMs contain compensator ICs. The different ICOMs are:

- 5C-ICOM contains an oscillator and a 5 part-per-million (±0.0005%) compensator IC. Provides compensation for EC-ICOMs.
- EC-ICOM contains an oscillator only. Requires external compensation from a 5C-ICOM.
- 2C-ICOM contains an oscillator and a 2 PPM (±0.0002%) compensator IC. Will not provide compensation for an EC-ICOM.

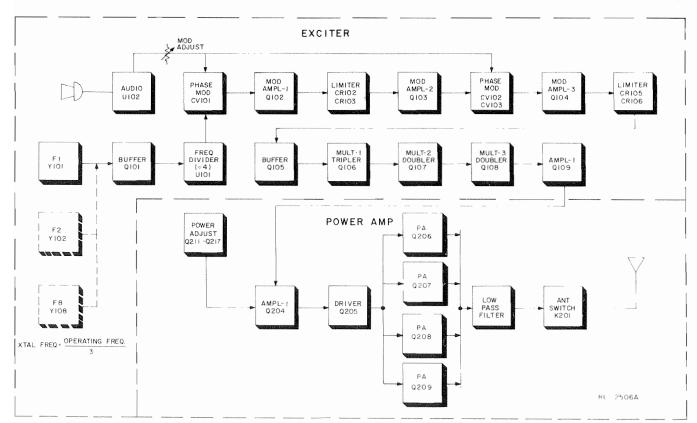


Figure 1 - Transmitter Block Diagram

The ICOMs are enclosed in an RF shielded can with the type ICOM (5C-ICOM, EC-ICOM or 2C-ICOM) printed on the top of the can.
Access to the oscillator trimmer is obtained through a hole on the top of the can.

Frequency selection is accomplished by switching the ICOM keying lead (terminal 6) to A- by means of the frequency selector switch on the control unit. In single-frequency radios, a jumper from H9 to H10 in the control unit connects terminal 6 of the ICOM to A-. The oscillator is turned on by applying a keyed +10 Volts to the external oscillator load resistor. RF bypassing is provided for all unused keying loads in eight frequency radios. In two frequency radios the six unused keying leads are shorted to ground.

#### — CAUTION —

All ICOMs are individually compensated at the factory and cannot be repaired in the field. Any attempt to repair or change an ICOM frequency will void the warranty.

In standard 5 PPM radios using EC-ICOMs, at least one 5C-ICOM must be used. The 5C-ICOM is normally used in the receiver F1 position, but can be used in any transmit or receive position. One 5C-ICOM can provide compensation for up to 15 EC-ICOMs in the transmit and receiver. Should the 5C-ICOM compensator fail in the open mode, the EC-ICOMs will still maintain 2 PPM frequency stability from 0°C to 55°C (+32°F to 131°F) due to the regulated compensation voltage (5 Volts) from the 10-Volt regulator IC. If desired, up to 16 5C-ICOMs may be used in the radio.

The 2C-ICOMs are self-compensated at 2 PPM and will not provide compensation for EC-ICOMs.

#### Oscillator Circuit

The quartz crystals used in ICOMs exhibit the traditional "S" curve characteristics of output frequency versus operating temperature.

At both the coldest and hottest temperatures, the frequency increases with increasing temperature. In the middle temperature range (approximately 0°C to +55°C), frequency decreases with increasing temperature.

Since the rate of change is nearly linear over the mid-temperature range, the output frequency change can be compensated by choosing a parallel compensation capacitor with a temperature coefficient approximately equal and opposite that of the crystal.

Figure 2 shows the typical performance of an uncompensated crystal as well as the typical performance of a crystal which has been matched with a properly chosen compensation capacitor.

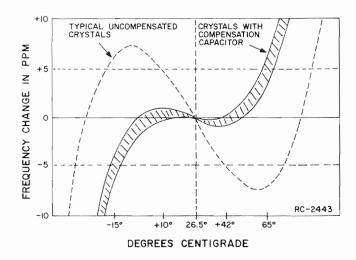


Figure 2 - Typical Crystal Characteristics

At temperatures above and below the mid-range, additional compensation must be introduced. An externally generated compensation voltage is applied to a varactor (voltage-variable capacitor) which is in parallel with the crystal.

A constant bias of 5 Volts (provided from Regulator IC U901 in parallel with the compensator) establishes the varactor capacity at a constant value over the entire midtemperature range. With no additional compensation, all of the oscillators will provide 2 PPM frequency stability from 0°C to 55°C (+32°F to 131°F).

#### Compensator Circuits

Both the 5C-ICOMs and 2C-ICOMs are temperature compensated at both ends of the temperature range to provide instant frequency compensation. An equivalent ICOM circuit is shown in Figure 3.

The cold end compensation circuit does not operate at temperatures above 0°C. When the temperature drops below 0°C, the circuit is activated. As the temperature decreases, the equivalent resistance decreases and the compensation voltage increases.

The increase in compensation voltage decreases the capacity of the varactor in the oscillator, increasing the output frequency of the ICOM.

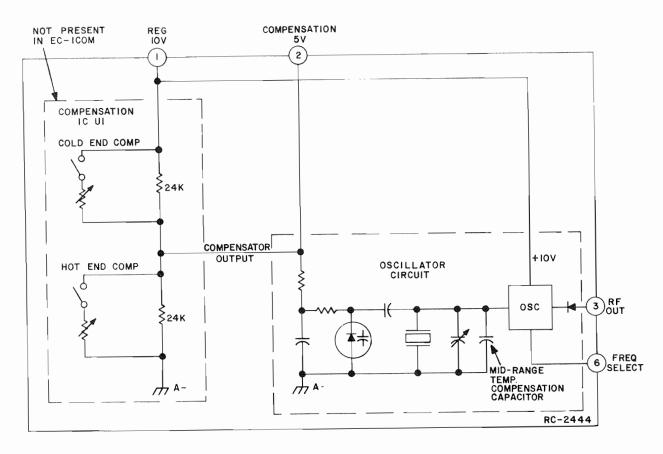


Figure 3 - Equivalent ICOM Circuit

The hot end compensation circuit does not operate at temperatures below +55°C. When the temperature rises above +55°C, the circuit is activated. As the temperature increases, the equivalent resistance decreases and the compensation voltage decreases. The decrease in compensation voltage increases the capacity of the varactor, decreasing the output frequency of the ICOM.

SERVICE NOTE: Proper ICOM operation is dependent on the closely-controlled input voltages from the 10-Volt regulator. Should all of the ICOMs shift off frequency, check the 10-Volt regulator module.

#### AUDIO IC

The transmitter audio circuitry is contained in audio IC UlO2. A simplified drawing of the audio IC is shown in Figure 4.

Audio from the microphone at pin 12 is coupled through pre-emphasis capacitor C1 to the base of Q1 in the operational amplifier-limiter circuit. Collector voltage for the transistorized microphone preamplifier is supplied from pin 11 through microphone collector load resistor R18 to pin 12.

The operational amplifier-limiter circuit consists of Q1, Q2 and Q3. Q3 provides limiting at high signal levels. The gain of the operational amplifier circuit is fixed by negative feedback through R19, R20 and the resistance in the network (pin 9).

The output of Q3 is coupled through a de-emphasis network (R10 and C3) to an active post-limiter filter consisting of C4, C5, C6, R11, R12, R13, R15, R17, and Q4.

Following the post-limiter filter is class A amplifier Q5. The output of Q5 is coupled through MOD ADJUST potentiometer R127 to the phase modulators.

 $\underline{\text{SERVICE NOTE}}\colon$  If the DC voltages to the Audio IC are correct and no audio output can be obtained, replace UlO2.

For radios equipped with Channel Guard, tone from the encoder is applied to the phase modulators through CHANNEL GUARD MOD ADJUST potentiometer R128, and resistors R110, R121 and R124. Instructions for setting R128 are contained in the modulation adjustment section of the Transmitter Alignment Procedure.

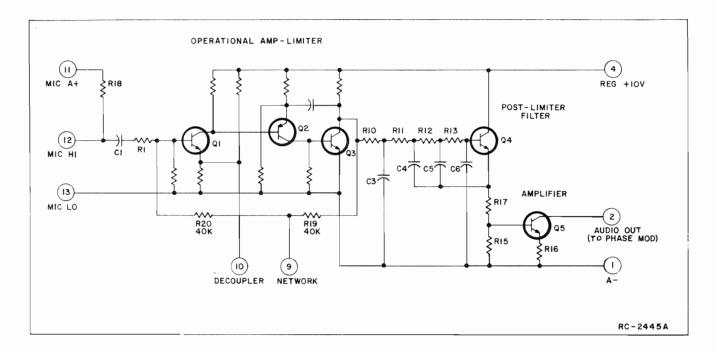


Figure 4 - Simplified Audio IC

#### FREQUENCY DIVIDER IC

The output at pin 3 of the selected ICOM is coupled through buffer amplifier Q101 to frequency divider U101, which divides the oscillator frequency by 4. The divider consists of two J-K flip-flops connected as a binary counter.

When the transmitter is not keyed (no ICOMs on), Q101 is saturated (turned on) with its collector voltage near zero. Keying the transmitter starts one of the ICOMs, and its output cuts Q101 on and off once each cycle. As Q101 turns off during each cycle, the drop in collector voltage causes the left flip-flop to change state. Assume the flip-flop was in the "0" state (the output at "Q" near A-). The first cycle of the oscillator output causes it to switch to the "1" stage (output at "Q" approximately 5 Volts). The second cycle will cause the flip-flop to switch back to the "0" state. Therefore, it requires two oscillator cycles to switch the left flip-flop through one complete cycle from "0" to "1" and back to "0".

When the left flip-flop switches from "1" to "0", it causes the right flip-flop to change state. It requires two cycles of the left flip-flop to switch the right flip-flop from "0" to "1" and back to "0". Therefore, four cycles of the oscillator output are required for each cycle of output from pin 9 of UlO1.

If U101 was operating into a pure resistive load, its output would be a square wave. However, the modulator circuit presents a tuned load to the IC, so that harmonics are filtered out and the waveform at the junction of C102 and C103 (modulator input) is essentially a sine wave at one-fourth the oscillator frequency. The output of the frequency divider is coupled through DC blocking capacitor C102 to the first modulator stage.

#### PHASE MODULATORS, AMPLIFIER & MULTIPLIERS

The first phase modulator is varactor (voltage-variable capacitor) CV101 in series with tunable coil L101. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator circuit through blocking capacitor C115 varies the bias of CV101, resulting in a phase modulated output. A voltage divider network (R108 and R109) provides the proper bias for varactors CV101, CV102 and CV103.

The output of the first modulator is coupled through blocking capacitor C106 to the base of Class A amplifier Q102. The first modulator stage is metered through a metering network consisting of R115, R150, C107 and CR101. Diodes CR102 and CR103 remove any amplitude modulation in the modulator output.

Following Q102 is another Class A Amplifier, Q103. The output of Q103 is applied to the second modulator stage. The second modulator consists of two cascaded modulator circuits consisting of CV102, L102, L103 and CV103. Following the second modulator is a Class A amplifier Q104. The output of the second modulator stage is metered through R133, R145, Cl17 and CR104, and is applied to the base of buffer Q105. Diodes CR105 and CR106 remove any amplitude modulation in the second modulator output.

Buffer Q105 is saturated when no RF signal is present. Applying an RF signal to Q105 provides a sawtooth waveform at its collector to drive the class C tripler, Q106. The tripler stage is metered through R146. The output of Q106 is coupled through tuned circuits T101, T102 and T103 to the base of doubler Q107. T101, T102 and T103 are tuned to one-fourth of the operating frequency. The doubler stage is metered through R147.

The output of Q107 is coupled through tuned circuits T104 and T105 to the base of second doubler Q108. T104 and T105 are tuned to one-half the operating frequency. Q108 is metered through R148.

The output of Q108 is coupled through three tuned circuits (T106, T107 and T108) to the base of amplifier Q109. The circuits are tuned to the transmitter operating frequency.

Q109 is a class C amplifier with a collector feed network consisting of C139, C141, L104, L108 and R143. The stage is metered through R149. The amplifier collector circuit consists of C142, C143, C146 and L105, and matches the amplifier output to the input of the power amplifier assembly.

#### POWER AMPLIFIER

The PA assembly uses six RF power transistors and seven transistors in the Power Control circuitry to provide a power output of 100 Watts. The broadband PA has no adjustments other than Power Control potentiometer R261.

Supply voltage for the PA is connected through power leads from the system board to feedthrough capacitors C297 and C298 on the bottom of the PA assembly. C297, C298 and C299, L297 and L298 prevent RF from getting on the Power leads. Diode CR295 will cause the main fuse in the fuse assembly to blow if the polarity of the power leads is reversed.

Centralized metering jack J205 is provided for use with GE Test Set Model 4EX3A11 or Test Kit 4EX8K12. The Test Set meters the Ampl-1 drive (exciter output), Ampl-1 power control, Driver and PA current. L251 through L257 in conjunction with bypass capacitors C4210 through C4216 keep RF off of the metering leads.

RF AMPLIFIERS

The exciter output is coupled through an RF cable to PA input jack J201. RF from the exciter is coupled through DC blocking capacitor C201 to the base of Class C amplifier Q204 through a matching network. The network matches 50-ohm input to the base of Q204, and consists of C205, C206, C207, L201 and L202. R203 and R204 lower the gain of the amplifier stage.

Part of the RF input is rectified by CR201 and used to activate the Power Control circuit. Another portion of the rectified RF is applied to voltage dividers R201 and R202 for metering the Ampl-1 drive at J205.

Collector voltage to Q204 (Ampl-1) is controlled by the Power Control Circuit, and is applied through a collector stabilizing network consisting of L258 and R272 and collector feed network L205 and C213. The collector voltage of Q204 is metered through R271 at J205.

Following Q204 is a matching network (C208 through C212, L204 and L206) to a resistive pad (R207, R208 and R209). The output of the resistor network is applied to the base of the Class C driver (Q205) through a matching network consisting of C218, C219, C220, L207 and L208. Resistors R207 through R215 lower the gain of driver Q205.

Collector voltage to Q205 is coupled through a collector stabilizing network consisting of L259 and R273 and collector feed network L211 and C226. Collector current for Q205 is metered across tapped manganin resistor R249 at J205 (DRIVER CURRENT). The reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 10 amperes full scale.

Following Q205 is a matching network (C221 through C225, L210 and L214) that matches the driver output to the input of the first power divider circuit (C230, C231, L214, L215 and L216).

The power amplifier stages consist of four identical paralleled Class C amplifiers (Q206 through Q209). The output of the first power divider circuit is applied to four additional power dividers. C234-L217 and C235-L218 provide drive for Q206 and Q207, while C236-L219 and C237-L220 provide drive for Q208 and Q209.

The output of C234-L217 is applied to the base of Q206 an impedance-matching network (L217, L221, C238, C242 and C243). Resistors R220 through R223, R236 and R237 hower the gain of Q206. Supply voltage for Q206 is coupled through a collector-stabilizing network consisting of L260 and R274 and collector feed network L223 and C270.

Collector current for Q206 through Q209 is metered across tapped maganin resistors R250 and R251 at J205 (PA CURRENT). The

reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 30 amperes full scale.

The output of Q206 is coupled through a matching network (C250, C251, L229, C258, C259, C266 and L237), applied to a lumped-constant combiner circuit (C280, L237 and L241), and added to the output of Q207. The outputs of Q206 and Q207 are added to the outputs of Q208 and Q209 through lumped-constant power combiner circuit C284, L249, C294, L250 and C285. The combined PA output is applied to 50-ohm microstrip W205, and then to an M-derived, constant K low-pass filter. The filter output is applied to the antenna through antenna switch K201.

Capacitors C286 through C293, C217, C228 and C233 provide ground isolation for  $\pm$  ground operation.

#### ---- WARNING -

The stud mounted RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

#### POWER CONTROL CIRCUIT

When the transmitter is keyed, rectified RF from CR201 is applied to the base of switch Q211, turning it on. Turning on Q211 turns on voltage regulator Q212 which supplies a constant voltage to Power Adjust potentiometer R261.

Q215, Q216 and Q217 operate as an amplifier chain to supply voltage to the collector of Q204 (Ampl-1). The setting of R261 determines the voltage applied to the base of Q215. The higher the voltage at the base of Q215, the harder the amplifiers conduct, supplying more collector voltage to Q204. The lower the voltage at the base of Q215, the less collector voltage is supplied to Q204. Reducing the supply voltage to Q204 reduces the drive to Q205, thereby reducing the power output of the PA. The power output can be adjusted by R261 from approximately 50 to 100 Watts (75 to 100 Watts at 25-30 MHz).

Temperature protection is provided by Q213, Q214, and thermistor RT201 which is mounted in the PA heatsink. Under normal operating conditions, the circuit is inactive (Q213 is on and Q214 is off). When the heatsink temperature reaches approximately 100°C, the resistance of RT201 decreases. This increases the base voltage applied to Q213, turning it off. Turning off Q213 allows Q214 to turn on, decreasing the voltage at Power Adjust potentiometer R261. This reduces the base voltage to Q215 which causes Q216 and Q217 to conduct

less, reducing the collector voltage to Q204 (Ampl-1). This reduces the transmitter output power, keeping the heatsink at a maximum of approximately 100°C. When the heatsink temperature decreases below 100°C, the temperature control circuit turns off, allowing the normal transmitter power output.

#### CARRIER CONTROL TIMER

The Carrier Control Timer option shuts off the transmitter on each transmission after a one-minute timing cycle, and alerts the operator that the transmitter is off by means of an alarm tone in the speaker. The transmitter can be turned on again by releasing and keying the push-to-talk switch on the microphone.

The timing cycle (transmitter keyed time) is normally set at the factory for a duration of one minute. A potentiometer permits the timing cycle to be adjusted from approximately 15 seconds to 3 minutes.

#### MAINTENANCE

#### DISASSEMBLY

To service the transmitter from the top:

 Pull the locking handle down, then pry up the top cover at the front notch and lift off the cover.

To service the transmitter from the bottom:

- 1. Pull the locking handle down and pull the radio out of the mounting frame.
- Remove the top cover, then loosen the two bottom cover retaining screws and remove the bottom cover (see Figure 5).
- 3. To gain access to the bottom of the exciter board, remove the six screws

  (A) holding the exciter board and its bottom cover to the module mounting frame, and remove the bottom cover.

To remove the exciter board from the radio:

- 1. Unplug the exciter/PA cable (B)
- 2. Remove the six screws (A) holding the exciter board and its bottom cover to the module mounting frame (see Figure 6).
- Press straight down on the plug-in exciter from the top to avoid bending the pins when unplugging the board from the system board jack.

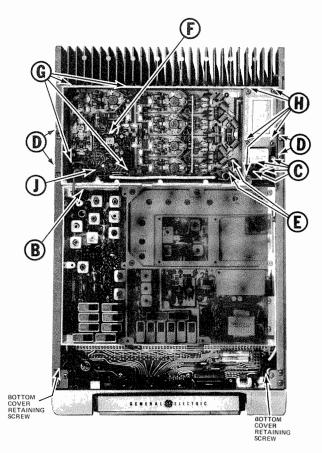


Figure 5 - Disassembly Procedure-Top View

To remove the PA assembly:

- 1. Remove the PA top cover and unplug the exciter/PA cable (B), the antenna, receiver and PTT cables (C).
- 2. Remove the four side-rail screws D, and unsolder the power cables from the bottom of the PA assembly if desired.

To remove the PA board:

- 1. Remove the PA top cover and unplug the exciter/PA cable (B) .
- 2. Unsolder the two feedthrough coils  $\stackrel{\textstyle (E)}{}$  and the thermistor leads  $\stackrel{\textstyle (F)}{}$ .
- 3. Remove the PA transistor hold-down nuts and spring washers on the bottom of the PA assembly.
- 4. Remove the four PA board mounting screws

  (G), the five screws in the filter casting (H), and the retaining screw in Q210 (J), and lift the board out.

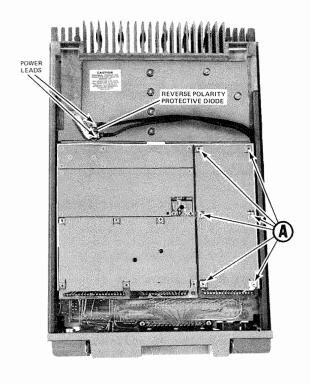


Figure 6 - Disassembly Procedure-Bottom View

- WARNING -

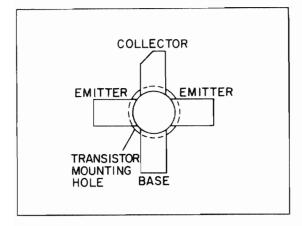
#### PA TRANSISTOR REPLACEMENT

The stud mounted RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled.

Use care in replacing transistors of this type.

To replace the PA RF transistors:

- 1. Unsolder one lead at a time with a 50-Watt soldering iron. Use a scribe to hold the lead away from the printed circuit board until the solder cools.
- 2. Turn the transmitter over.
- 3. Hold the body of the transistor to prevent it from turning. Remove the transistor hold-down nut and spring washer through the hole in the heatsink with an 11/32-inch nut-driver. Lift out the transistor, and remove the old solder from the printed circuit board with a de-soldering tool such as a SOLDA PULLT<sup>®</sup>. Special care should be taken to prevent damage to the printed circuit board runs.



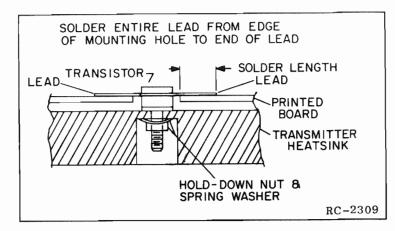


Figure 7 - Lead Identification

Figure 8 - Lead Forming

- 4. Trim the new transistor leads (if required) to the lead length of the removed transistor. Cut the collector lead at a 45° angle for future identification (see Figure 7). The letter "C" on the top of the transistor indicates the collector.
- 5. Apply a coating of silicon grease around the transistor mounting surface, and place the transistor in the mounting hole. Align the leads as shown in the Outline Diagram. Then hold the body of the transistor and replace the holding-down nut and spring-washer using moderate torque (8 inch-pounds). A torque wrench must be used for this adjustment since transistor damage can result if too little or too much torque is used.
- 6. Make sure that the transistor leads are formed as shown in Figure 8 so that the leads can be soldered to the printed circuit pattern, starting from the inner edge of the mounting hole.
- 7. Solder the leads to the printed circuit pattern. Start at the inner edge of mounting hole and solder the remaining length of transistor lead to the board. Use care not to use excessive heat that causes the printed wire board runs to lift up from the board. Check for shorts and solder bridges before applying power.

- CAUTION -

Failure to solder the transistor leads as directed may result in the generation of RF loops that could damage the transistor or may cause low power output.

GENERAL ELECTRIC COMPANY • MOBILE COMMUNICATIONS DIVISION WORLD HEADQUARTERS • LYNCHBURG, VIRGINIA 24502 U.S.A.



#### TRANSMITTER ALIGNMENT

#### EQUIPMENT REQUIRED

- 1. GE Test Set Model 4EX3All or Test Kit 4EX8K12.
- A 50-ohm wattmeter connected to antenna jack J906.
- 3. A frequency counter.

#### PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Place ICOMs on Exciter Board (crystal frequency = operating frequency ÷ 3).
- 2. For a large change in frequency or a badly mis-aligned transmitter, pre-set the slugs in T101 through T108, and L101, L102 and L103 to the bottom of the coil form.

NOTE

The tuning frequency for multi-frequency transmitters is determined by the operating frequency and the frequency spread between transmitters. Refer to the table below for maximum frequency spread.

3. For multi-frequency transmitters with a frequency spread less than that specified in column (1), tune the transmitters to the lowest frequency.

For frequency spread exceeding the limits specified in column (1), tune the transmitters using a center frequency tune up ICOM. Except the maximum frequency spread can be extended to the limits specified in column (3) with 1 dB degradation.

For tuning L101, L102, L103. Always tune L101, L102, L103 on the lowest frequency.

#### Multi-frequency Transmitter Tuning

Transmitter Frequency Range	MAXIMUM FREQUENCY SPREAD						
	(1) without center tuning	with center tuning	with center tuning (1dB degradation)				
25 - 30 MHz	.080 MHz	.160 MHz	.320 MHz				
30 - 36 MHz	.100 MHz	.200 MHz	.400 MHz				
36 - 42 MHz	.120 MHz	.240 MHz	.470 MHz				
42 - 50 MHz	.140 MHz	.280 MHz	.540 MHz				

- 4. Connect the red plug on the GE Test Set to the System Board metering jack, and the black plug to the Exciter metering jack. Set the polarity to +, and set the range to the Test 1 position (1-Volt position for 4EXSK12) for all adjustments. NOTE: With the Test Set connected to the PA metering jack, the voltage reading at position "F" with the HIGH SENSITIVITY button pressed may be converted to driver collector current by reading the current as 10 amperes full scale. The voltage reading at position "G" with the HIGH SENSITIVITY button pressed may be converted to PA collector current by reading the current as 30 amperes full scale.
- 5. All adjustments are made with the transmitter keyed. Unkey the transmitter between steps to avoid unnecessary heating.

STEP	METER POSITION	TUNING CONTROL	METER READING	PROCEDURE
1.	MOD-1 PRNZ	L101	Maximum	Tune L101 for maximum meter reading.
2.	в Р/М	L102 & L103	Maximum	Tune L102 and then L103 for the maximum meter reading.
3.	C MULT-1 P » N 3	T101 & T102	See Procedure	Tune 1.101 for maximum dip meter reading, and then tune T102 for maximum meter reading.
4.	D MULT-2 P** 1	T103, T102, T101 & T104	See Procedure	Tune T103 for maximum meter reading and re-adjust T102 and T101 for maximum meter reading. Then tune T104 for a dip in meter reading.
5.	MULT-3 PIP 7	T105, T104, T106 & T107	See Procedure	Tune T105 for maximum meter reading and re-adjust T104 for maximum meter reading. Then tune T106 for a dip in meter reading and T107 for maximum meter reading.
6.	G AMPL-1 PIN 6	T108, T107 & T106	See Procedure	Tune T108 for maximum meter reading, and then re-adjust T107 and T106 for maximum meter reading.
7.	D AMPL-1 (A) TOP (On PA)	C143, C156	Maximum	Move the black metering plug to the Power Amplifier metering jack and tune C143 and C156 for maximum meter reading.
8.		R261		With the battery voltage at 13.4 Volts or the PA collector voltage at 12.4 Volts, set Power Adjust potentiometer R261 on the PA board for the desired power output (from 50 to 100 Watts at 30-50 MHz, or from 75 to 100 Watts at 25-30 MHz).  If the battery voltage is not at 13.4 Volts or the collector voltage at 12.4 Volts and full rated output is desired (50 to 100 Watts at 30-50 MHz, or from 75 to 100 Watts at 25-30 MHz), set R261 for the output power according to the battery voltage or collector voltage shown in Figure 10.
		3		NOTE  The PA collector voltage is measured as described in the PA POWER INPUT section.



ANTENNA JACK J906

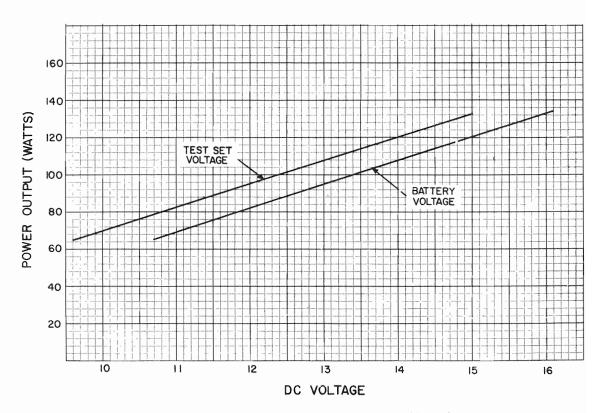


Figure 10 - Power Output Setting Chart

# **ALIGNMENT PROCEDURE**

25-50 MHz, 100-WATT TRANSMITTER

# M FREQUENCY ADJUSTMENT

requency to determine if any adjustment is required. The freth a frequency meter or counter with an absolute accuracy that than the tolerance to be maintained, and with the entire radio an ambient temperature of  $26.5\,^{\circ}\mathrm{C}$  (79.8°F).

uld be reset only when the frequency shows deviations in excess  $\dot{\ }$ 

en the radio is at 26.5°C (79.8°F).

y other temperature within the range of  $-5^{\circ}$ C to  $+55^{\circ}$ C

ation limit ( $\pm 2$  PPM or  $\pm 5$  PPM) at any temperature within f -40°C to -5°C (-40°F to +23°F) or +55°C to +70°C 158°F).

s required, pry up the cover on the top of the ICOM to expose e of the following procedures:

an ambient temperature of 26.5°C (79.8°F), set the oscillator ng frequency.

 $\underline{t}$  at an ambient temperature of 26.5°C, setting errors can be

ing error to  $\pm 0.6$  PPM (which is considered reasonable for 5 PPM

the radio at 26.5°C (±5°C) and set the oscillator to

the radio at 26.5°C ( $\pm 10$ °C) and offset the oscillator, as a of actual temperature, by the amount shown in Figure 9.

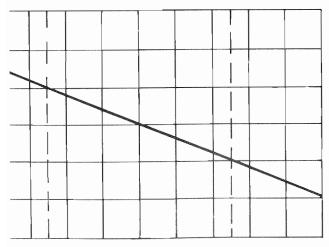
ing error to  $\pm 0.35$  PPM (which is considered reasonable for : Maintain unit at 26.5°C ( $\pm 5$ °C) and offset the oscillator, n of actual temperature, by the amount shown in Figure 9.

e ambient temperature of the radio is  $18.5^{\circ}$ C (65.4°F). At urve shows a correction factor of 0.3 PPM. (At 25 MHz, 1 PPM PPM is 50 Hz).

frequency of 50 MHz, set the oscillator for a reading of 15 Hz an the licensed operating frequency. If a negative correction temperatures above 26.5°C), set the oscillator for the indie licensed operating frequency.

#### DEGREES FAHRENHEIT

69.0 72.6 76.6 79.8 83.4 87.0 90.6 94.2 97.8



20.5 22.5 24.5 26.5 28.5 30.5 32.5 34.5 36.5

-5° LIMIT REF. +5° LIMIT DEGREES CENTIGRADE

RC-2453

**METERING** POWER **ADJUST** R261 C143 -**EXCITER** METERING -**JACK** J103 MOD **ADJUST** R127 F7 SYSTEM BOARD **CHANNEL METERING GUARD JACK** MOD **ADJUST** R128 GENERAL SELECTRIC **ANTENNA JACK** 

#### TRANSMITTER ALIGNMENT

#### EQUIPMENT REQUIRED

J906

- GE Test Set Model 4EX3All or Test Kit 4EX8Kl2.
- 2. A 50-ohm wattmeter connected to antenna jack J906.
- 3. A frequency counter.

#### PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Place ICOMs on Exciter Board (crystal frequency = operating frequency = 3).
- For a large change in frequency or a badly mis-aligned transmitter, pre-set the slugs in T101 through T108, and L L103 to the bottom of the coil form.

The tuning frequency for multi-frequency transmitters is determined by the operating frequency and the frequency transmitters. Refer to the table below for maximum frequency spread.

3. For multi-frequency transmitters with a frequency spread less than that specified in column (1), tune the transmi quency.
For frequency spread exceeding the limits specified in column (1), tune the transmitters using a center frequency maximum frequency spread can be extended to the limits specified in column (3) with 1 dB degradation.

For tuning L101, L102, L103. Always tune L101, L102, L103 on the lowest frequency.

Multi-frequency Transmitter Tuning

Transmitter Frequency Range		MAXIMUM FREQUENCY SF	READ
	(1) without center tuning	with center tuning	with center
25 - 30 MHz	.080 MHz	.160 MHz	
30 - 36 MHz	.100 MHz	.200 MHz	
36 - 42 MHz	.120 MHz	.240 MHz	
42 - 50 MHz	.140 MHz	.280 MHz	

- 4. Connect the red plug on the GE Test Set to the System Board metering jack, and the black plug to the Exciter mete to +, and set the range to the Test 1 position (1-Volt position for 4EXBK12) for all adjustments. NOTE: With th PA metering jack, the voltage reading at position "F" with the HIGH SENSITIVITY button pressed may be converted to by reading the current as 10 amperes full scale. The voltage reading at position "G" with the HIGH SENSITIVITY be verted to PA collector current by reading the current as 30 amperes full scale.
- 5. All adjustments are made with the transmitter keyed. Unkey the transmitter between steps to avoid unnecessary he

STEP	METER POSITION	TUNING CONTROL	METER READING	PROCEDURE
1.	MOD-1 PENZ	L101	Maximum	Tune L101 for maximum meter reading.
2.	B PIN 1	L102 & L103	Maximum	Tune L102 and then L103 for the maximum
3.	C MULT-1 P=N 3	T101 & T102	See Procedure	Tune 101 for maximum dip meter reading, maximum meter reading.
4.	MULT-2 PMJ L	T103, T102, T101 & T104	See Procedure	Tune T103 for maximum meter reading and for maximum meter reading. Then tune T1 reading.
5.	MULT-3 PIN 7	T105, T104, T106 & T107	See Procedure	Tune T105 for maximum meter reading and meter reading. Then tune T106 for a dip for maximum meter reading.
6.	G AMPL-1 PIN 6	T108, T107 & T106	See Procedure	Tune T108 for maximum meter reading, and T106 for maximum meter reading.
7.	D AMPL-1 PAN II DRIVE PON (On PA) AMP	C143, C156	Maximum	Move the black metering plug to the Powel and tune C143 and C156 for maximum meter
8.		R261		With the battery voltage at 13.4 Volts of at 12.4 Volts, set Power Adjust potention for the desired power output (from 50 to or from 75 to 100 Watts at 25-30 MHz).  If the battery voltage is not at 13.4 Vo.
			THE LAW CAR.	tage at 12.4 Volts and full rated output watts at 30-50 MHz, or from 75 to 100 War R261 for the output power according to the lector voltage shown in Figure 10.
		· manufacture town		The PA collector voltage is measured the PA POWER INPUT section.

) - Frequency Characteristics Vs. Temperature

#### **MODULATION LEVEL ADJUSTMENT**

The MOD ADJUST (R127) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

#### TEST EQUIPMENT

- 1. An audio oscillator (GE Model 4EX6Al0)
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. GE Test Set Models 4EX3All or 4EX8Kl2

#### PROCEDURE

- 1. Connect the audio oscillator and the meter across audio input terminals J10 (Green-Hi) and J11 (Black-Lo) on GE Test Set, or across P902-6 (Mike High) through a 0.5 microfarad (or larger) DC blocking capacitor, and P902-5 (Mike-Low) on the System Board.
- 2. Adjust the audio oscillator for 1-Volt RMS at 1000 Hz.
- 3. For transmitters without Channel Guard, set MOD ADJUST R127 for a 4.5-kilohertz swing with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set Channel Guard MOD ADJUST R128 for zero tone deviation. Next, with the 1-Volt signal at 1000 Hz applied, set MOD ADJUST R127 for a 3.75 kHz deviation. Then remove the signal from the audio oscillator and set Channel Guard MOD ADJUST R128 for 0.75 kHz tone deviation.
- 5. For multi-frequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

#### PA POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA supply voltage and PA current, and using the following formula:

where:

P; is the power input in Watts,

PA voltage is measured with Test Set Model 4EX3All in Position G on the 15-Volt range (read as 15 Volts full scale), and with the polarity switch in the (-) position. With Test Set Model 4EX8K12, use the B+ position and the 1-Volt range (read as 15 Volts full scale), with the HIGH SENSITIVITY button pressed and the polarity switch in the (-) position.

PA current is measured with the Test Set in Position G in the Test 1 position, and with the HIGH SENSITIVITY button pressed (30 amperes full scale).

P. = 12.4 Volts x 8.5 amperes - 105.4 Watts

#### ICOM FREQUENCY ADJUSTMENT

First, check the frequency to determine if any adjustment is required. The frequency should be set with a frequency meter or counter with an absolute accuracy that is 5 to 10 times better than the tolerance to be maintained, and with the entire radio as near as possible to an ambient temperature of 26.5°C (79.8°F).

MASTR II ICOMs should be reset only when the frequency shows deviations in excess of the following limits:

- $\pm 0.5$  PPM, when the radio is at 26.5°C (79.8°F).
- $\pm 2$  PPM at any other temperature within the range of  $-5\,^{\circ}\mathrm{C}$  to  $+55\,^{\circ}\mathrm{C}$  $(+23 \,^{\circ}\text{F} \text{ to } +131 \,^{\circ}\text{F})$ .
- The specification limit (±2 PPM or ±5 PPM) at any temperature within the ranges of  $-40^{\circ}$ C to  $-5^{\circ}$ C ( $-40^{\circ}$ F to  $+23^{\circ}$ F) or  $+55^{\circ}$ C to  $+70^{\circ}$ C  $(+131^{\circ}F \text{ to } +158^{\circ}F)$ .

If an adjustment is required, pry up the cover on the top of the ICOM to expose the trimmer, and use one of the following procedures:

If the radio is at an ambient temperature of 26.5°C (79.8°F), set the oscillator for the correct operating frequency.

If the radio is not at an ambient temperature of 26.5°C, setting errors can be minimized as follows:

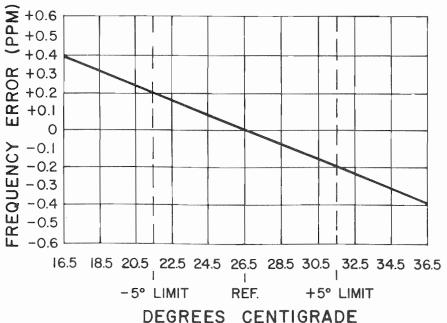
- To hold setting error to  $\pm 0.6$  PPM (which is considered reasonable for 5 PPM
  - 1. Maintain the radio at 26.5°C ( $\pm 5$ °C) and set the oscillator to desired frequency, or-
  - 2. Maintain the radio at  $26.5\,^{\circ}\mathrm{C}$  ( $\pm10\,^{\circ}\mathrm{C}$ ) and offset the oscillator, as a function of actual temperature, by the amount shown in Figure 9.
- To hold setting error to ±0.35 PPM (which is considered reasonable for 2 PPM ICOMs): Maintain unit at 26.5°C (±5°C) and offset the oscillator, as a function of actual temperature, by the amount shown in Figure 9.

For example: Assume the ambient temperature of the radio is 18.5°C (65.4°F). At that temperature, the curve shows a correction factor of 0.3 PPM. (At 25 MHz, 1 PPM is 25 Hz. At 50 MHz, 1 PPM is 50 Hz).

With an operating frequency of 50 MHz, set the oscillator for a reading of 15 Hz (0.3 x 50 Hz) higher than the licensed operating frequency. If a negative correction factor is obtained (at temperatures above 26.5°C), set the oscillator for the indicated PPM lower than the licensed operating frequency.

#### DEGREES FAHRENHEIT

61.8 65.4 69.0 72.6 76.6 79.8 83.4 87.0 90.6 94.2 97.8



RC-2453

Figure 9 - Frequency Characteristics Vs. Temperature

METERING JACK J205 POWER **ADJUST** R261 C143 -EXCITER METERING . **JACK** J103 MOD **ADJUST** R127 CHANNEL **GUARD** MOD **ADJUST** R128

# **TEST PROCEDURES**

These Test Procedures are designed to assist you in servicing a transmitter that is operating—but not properly. Problems encountered could be low power output, tone and voice deviation, defective audio sensitivity, and modulator adjust control set too high. Once a defect is pin-pointed,

refer to the "Service Check" and the additional corrective measures included in the Transmitter Troubleshooting Procedure. Before starting with the Transmitter Test Procedures, be sure the transmitter is tuned and aligned to the proper operating frequency.

----- CAUTION -----

Before bench testing the MASTR II Mobile Radio, be sure of the output voltage characteristics of your bench power supply.

To protect the transmitter power output transistors from possible instant destruction, the following input voltages must not be exceeded:

Transmitter unkeyed: 20 Volts
Transmitter keyed (50 ohm resistive load): 18 Volts
Transmitter keyed (no load or non-resistive load): 15.5 Volts

These voltages are specified at the normal vehicle battery terminals of the radio and take the voltage drop of standard cables into account. The voltage limit shown for a non-optimum load is for "worst case" conditions. For antenna mismatches likely to be encountered in practice, the actual limit will approach the 18 Volt figure.

Routine transmitter tests should be performed at EIA Standard Test Voltages (13.6 VDC for loads of 6 to 16 amperes; 13.4 VDC for loads of 16 to 36 amperes). Input voltages must not exceed the limits shown, even for transient peaks of short duration.

Many commonly used bench power supplies cannot meet these requirements for load regulation and transient voltage suppression. Bench supplies which employ "brute force" regulation and filtering (such as Lapp Model 73) may be usable when operated in parallel with a 12-Volt automotive storage battery.

#### TEST EQUIPMENT REQUIRED

for test hookup as shown:

- 1. Wattmeter similar to: 2. VTVM similar to: 3.
  - 3. Audio Generator similar to:

Bird # 43 Jones # 711N Triplett # 850 Heath # IM-21 GE Model 4EX6Al0

- 4. Deviation Meter (with a .75 kHz scale) similar to:
  Measurements # 720
- 5. Multimeter similar to:

GE TEST SET MODEL 4EX3A11, MODEL 4EX8K12 or 20,000 ohms-per-Volt voltmeter

#### TEST PROCEDURE

- 1. Connect transmitter output from the antenna jack to the the wattmeter is terminated into a 50-ohm load.
- 2. Key the transmitter and check the wattmeter for the de

#### SERVICE CHECK

Check the setting of the Power Adjust Control (R261).

Refer to the QUICK CHECKS on the Transmitter Troublesh

## VOICE DEVIATION, SYMMETRY

#### **TEST PROCEDURE**

- 1. Connect the test equipment to the transmitter as shown
- 2. In radios with Channel Guard, set Channel Guard Mod Ad
- 3. Set the Audio generator output to 1.0 VOLTS RMS and  ${
  m fr}$
- 4. Key the transmitter and adjust Deviation Meter to carr
- 5. Deviation reading should be  $\pm 4.5~\mathrm{kHz}$  in radios without Channel Guard.
- 6. If necessary, adjust MOD ADJUST control R127 for the p deviation, whichever is greater.
- NOTES: -- MASTR II transmitters are adjusted for 4.5 kHz
  The factory adjustment will prevent the transm
  than 5.0 kHz under the worst conditions of fre
  temperature.
- 7. If the deviation reading plus (+) or minus (-) differs as shown in the Transmitter Alignment Chart.
- 8. Check Audio Sensitivity by reducing generator output u without Channel Guard, or 2.25 kHz for radios with Chamillivolts. If not, refer to the Transmitter Troubles

# D

"Service Check" and the additional asures included in the Transmitter ng Procedure. Before starting with er Test Procedures, be sure the s tuned and aligned to the proper quency.

the output voltage

ssible instant des-

#### .5 Volts

terminals of the count. The voltage litions. For antenna limit will approach

of 16 to 36 amperes). cransient peaks of

requirements for load tes which employ 73) may be usable attery.

rator similar to:

del 4EX6Al0

oltmeter

A11,

#### **POWER MEASUREMENT**

#### **TEST PROCEDURE**

- 1. Connect transmitter output from the antenna jack to the wattmeter through a 50-ohm coaxial cable. Make sure the wattmeter is terminated into a 50-ohm load.
- 2. Key the transmitter and check the wattmeter for the desired power output.

#### SERVICE CHECK

Check the setting of the Power Adjust Control (R261).

Refer to the QUICK CHECKS on the Transmitter Troubleshooting Procedure.

# **VOICE DEVIATION, SYMMETRY AND AUDIO SENSITIVITY**

#### TEST PROCEDURE

- 1. Connect the test equipment to the transmitter as shown.
- 2. In radios with Channel Guard, set Channel Guard Mod Adjust R128 for zero tone deviation.
- 3. Set the Audio generator output to 1.0 VOLTS RMS and frequency to 1 kHz.
- 4. Key the transmitter and adjust Deviation Meter to carrier frequency.
- 5. Deviation reading should be  $\pm 4.5$  kHz in radios without Channel Guard, and  $\pm 3.75$  kHz in radios with Channel Guard.
- 6. If necessary, adjust MOD ADJUST control R127 for the proper deviation on plus (+) or minus (-) deviation, whichever is greater.
- NOTES: -- MASTR II transmitters are adjusted for 4.5 kHz deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5.0 kHz under the worst conditions of frequency, voltage and temperature.
- 7. If the deviation reading plus (+) or minus (-) differs by more than 0.5 kHz, recheck Steps 1 and 2 as shown in the Transmitter Alignment Chart.
- 8. Check Audio Sensitivity by reducing generator output until deviation falls to 3.0 kHz for radios without Channel Guard, or 2.25 kHz for radios with Channel Guard. Voltage should be LESS than 120 millivolts. If not, refer to the Transmitter Troubleshooting Procedure.

# TEST PROCED

- 1. Set up the
- 2. Remove the
- 3. Key the tra

#### NOTES:

- l. On units su carefully t Alignment (
- 2. The Tone De is changed.

ter through a 50-ohm coaxial cable. Make sure

ver output.

cocedure.

#### **AUDIO SENSITIVITY**

for zero tone deviation.

o 1 kHz.

ency.

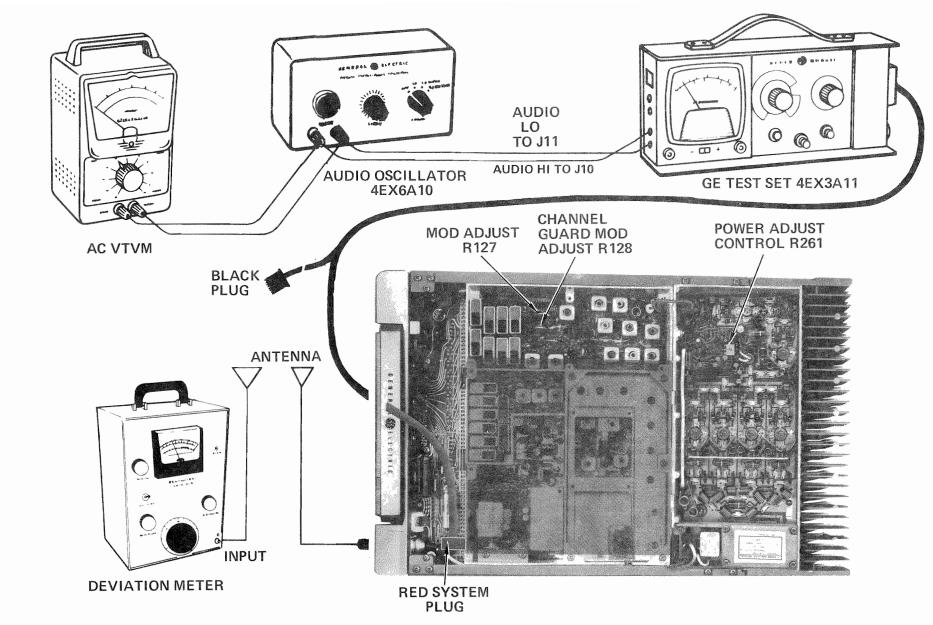
Guard, and ±3.75 kHz in radios with

iation on plus (+) or minus (-)

n at the factory.
m deviating more
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than 0.5 kHz, recheck Steps 1 and 2

ation falls to 3.0 kHz for radios d. Voltage should be LESS than 120 rocedure.



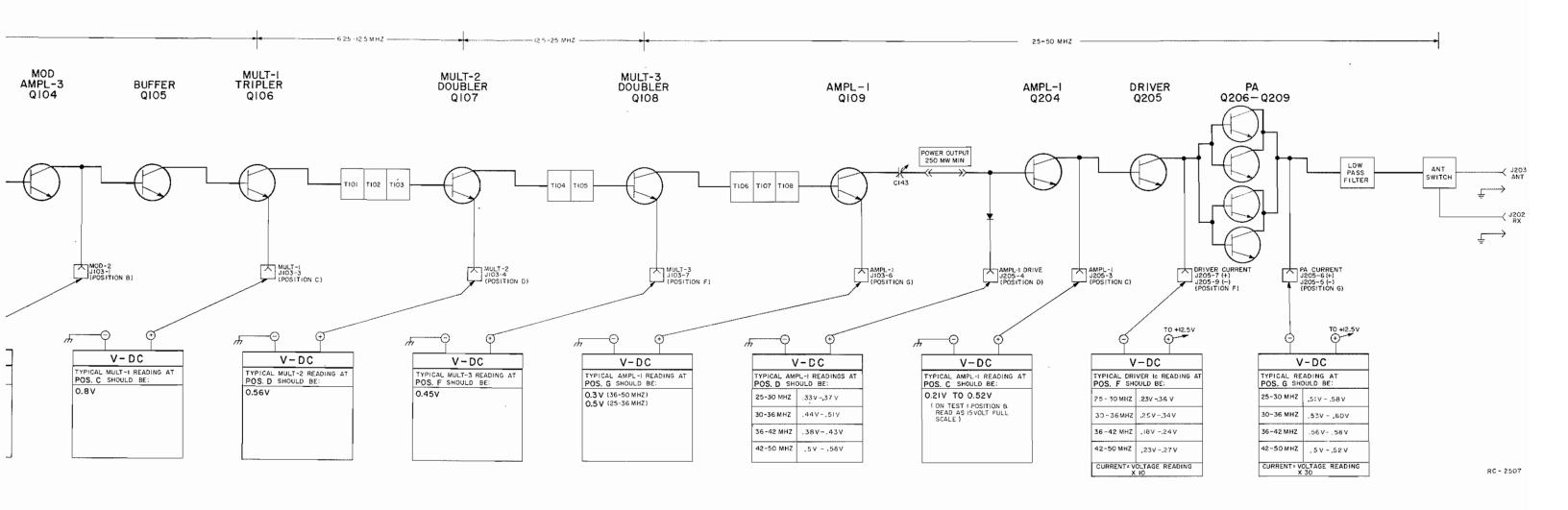
## TONE DEVIATION WITH CHANNEL GUARD

#### **TEST PROCEDURE**

- 1. Set up the Deviation Meter and monitor the output of the transmitter.
- 2. Remove the 1000 Hz signal from the audio generator.
- 3. Key the transmitter and check for 0.75 kHz deviation. If the reading is low or high, adjust Channel Guard MOD ADJUST R128 for a reading of 0.75 kHz.

#### NOTES:

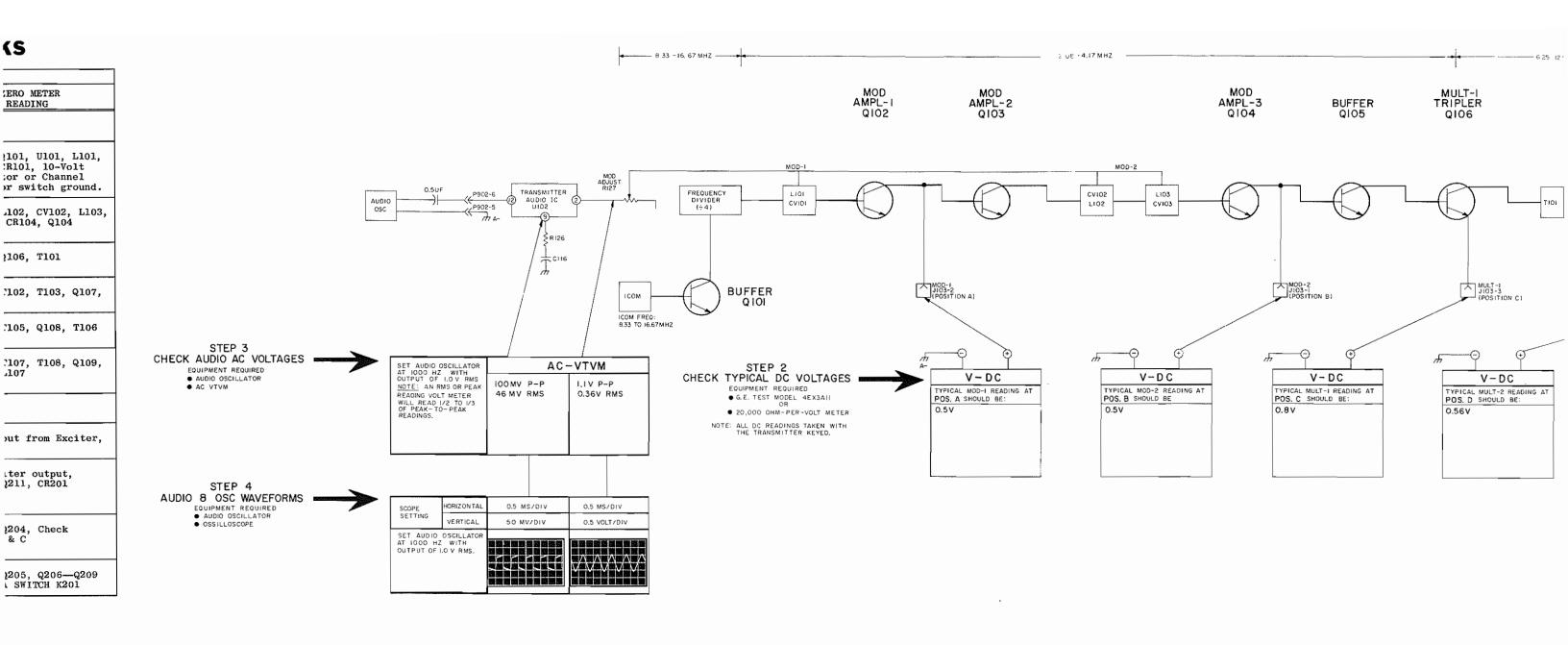
- 1. On units supplied with Channel Guard, the Phase Modulator Tuning should be adjusted carefully to insure proper performance. (Refer to Steps 1 and 2 in the Transmitter Alignment Chart).
- 2. The Tone Deviation Test Procedures should be repeated every time the Tone Frequency is changed.



# TROUBLESHOOTING PROCEDURE

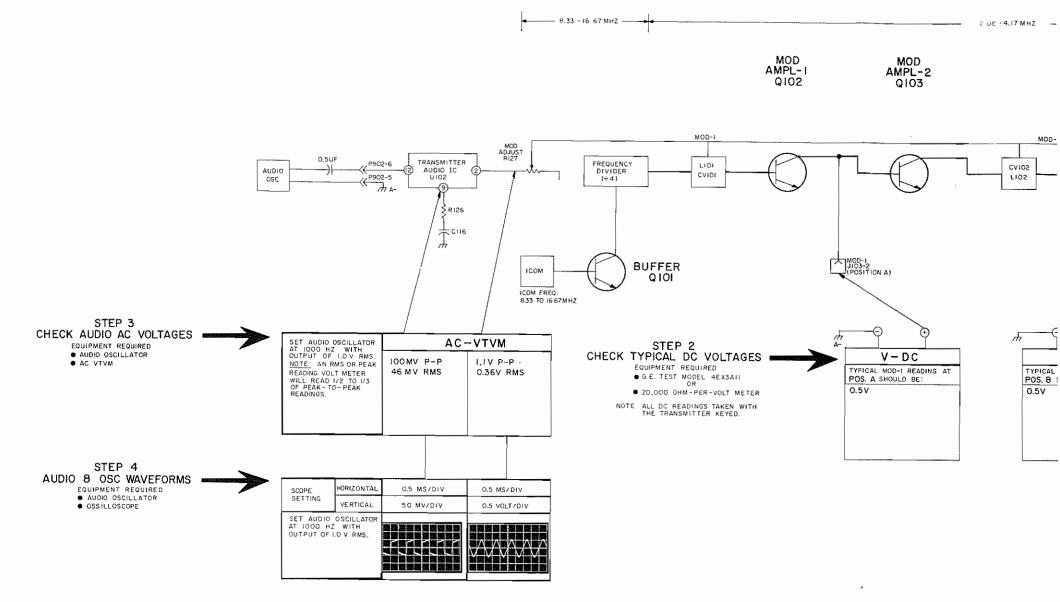
25-50 MHz, 100-WATT TRANSMITTER

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# **STEP I - QUICK CHECKS**

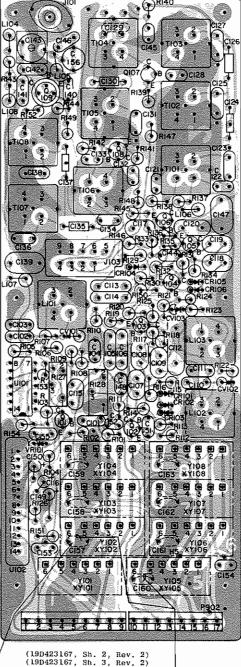
		PROBABLE DEFECTI	VE STAGE		
METER POSITION GE TEST SET	HIGH METER READING	LOW METER READING	ZERO METER READING		
		EXCITER			
A (MOD-1)	Q102, 10- Volt regulator	Q102, CV101, L101, 10-Volt regulator	ICOM, Q101, U101, L101, Q102, CR101, 10-Volt regulator or Channel Selector switch ground.		
B (MOD-2)	Q104, 10- Volt regulator	Q103, L102, L103, CV102, CV103, Q104	Q103, L102, CV102, L103, CV103, CR104, Q104		
C (MULT-1)	Q105, Q106 T101	Q105, Q106	Q105, Q106, T101		
D (MULT-2)	Q107, T104	T101, T102, T103, Q107	T101, T102, T103, Q107,		
F (MULT-3)	Q108, T106	T104, T105, Q108	T104, T105, Q108, T106		
G (AMPL-1)	Q109, C146, R144	T106, T107, T108, Q109, L108	T106, T107, T108, Q109, L104, L107		
	P	OWER AMPLIFIER			
"D" (AMPL-1 DRIVE)		Low Output from Exciter	No output from Exciter, CR201		
"C" (AMPL-1 CONTROL VOLT- AGE)	Q217	Q217	No Exciter output, Q217, Q211, CR201		
"F" (DRIVER CURRENT)	Q205	Q205, Low Output from Q204	Q205, Q204, Check Pos. D & C		
"G" (PA CURRENT)	Q206, Q207 Q208, Q209	Q204, Q205, Q206—Q209	Q204, Q205, Q206-Q209 ANTENNA SWITCH K201		



#### EXCITER BOARD

# SOLDER SIDE

COMPONENT SIDE



(19D423167, Sh. 2, Rev. 2)

IN EIGHT-FREQUENCY EXCITERS (GROUPS 5-8), CAPACITORS C157-C163 ARE CLIPPED OUT AS REQUIRED TO MEET THE CUSTOMER REQUIREMENTS FOR FREQUIREMENTS; IF CUSTOMER MANTS 1COMS FOR FIT, F2, F5, F7, THEN CAPACITORS C157, C160, AND C162 ARE CLIPPED OUT. C158, C159, C161, C163 ARE LEFT IN.

IN TWO-FREQUENCY EXCITERS (GROUPS 1-4) C157 IS CLIPPED OUT FOR COMBINATIONS WITH 2 TRANSMIT ICOMS. DA JUMPERS ARE PRESENT ON FREQUENCY SWITCHING LINES OF OTHER SIX ICOM CIRCUITS AS SHOWN.

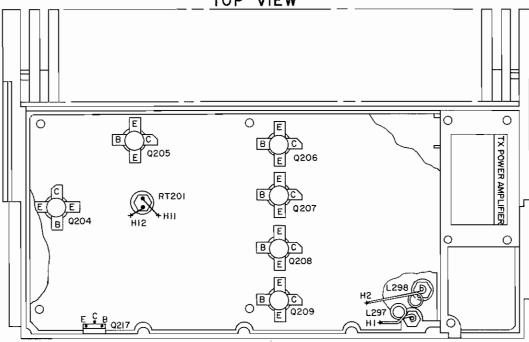
#### (19D423234, Rev. 3)

25-50 MHz, 100-WATT TRANSMITTER

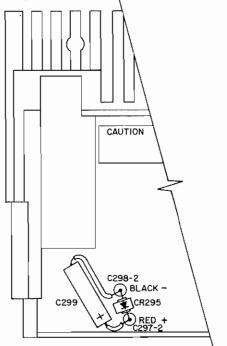
**OUTLINE DIAGRAM** 

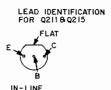
12 Issue 7

# PA ASSEMBLY TOP VIEW



# BOTTOM VIEW



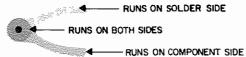


IN-LINE VIEW FROM LEAD END

LEAD IDENTIFICATION

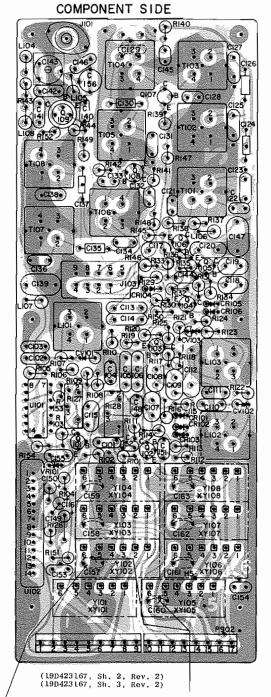
IN-LINE TRIANGULAR
VIEW FROM LEAD END

NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.



(19R622110, Rev. 7)

#### EXCITER BOARD

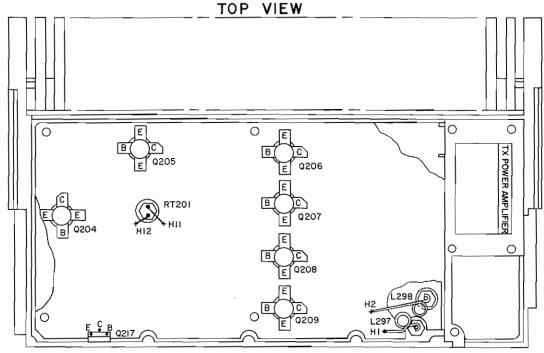


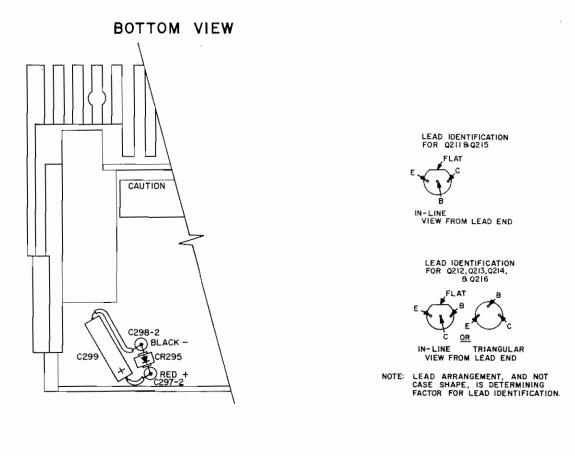
FREQUENCY EXCITERS (GROUPS 5-8), CAPACITORS 3 ARE CLIPPED OUT AS REQUIRED TO MEET THE PROUREMENTS FOR REQUENCIES. EXAMPLE: IF WANTS ICOMS FOR FI; F2, F5, F7, THEN CAPACITORS 60, AND C162 ARE CLIPPED OUT. C158, C159, C161, LEFT IN.

IN TWO-FREQUENCY EXCITERS (GROUPS 1-4) CIST IS CLIPPED OUT FOR COMBINATIONS WITH 2 TRANSMIT ICOMS. DA JUMPERS ARE PRESENT ON FREQUENCY SWITCHING LINES OF OTHER SIX ICOM CIRCUITS AS SHOWN.

(19D423234, Rev. 3)

# PA ASSEMBLY



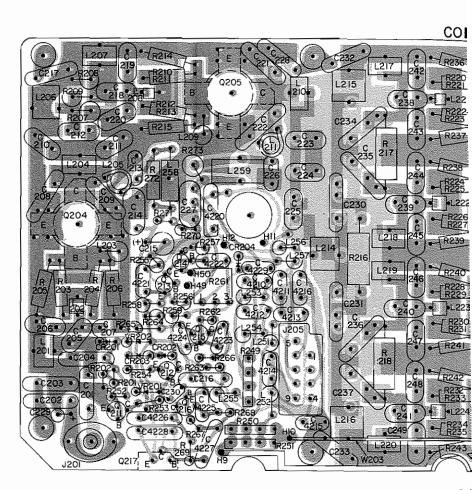


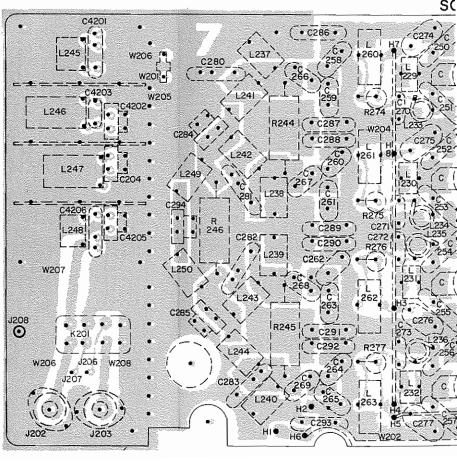
(19R622110, Rev. 7)

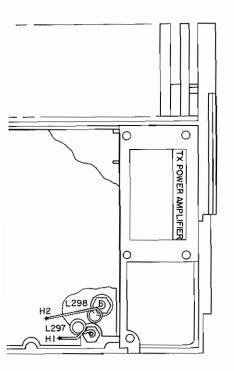
RUNS ON SOLDER SIDE

- RUNS ON COMPONENT SIDE

RUNS ON BOTH SIDES







LEAD IDENTIFICATION FOR Q2118Q215



IN-LINE VIEW FROM LEAD END

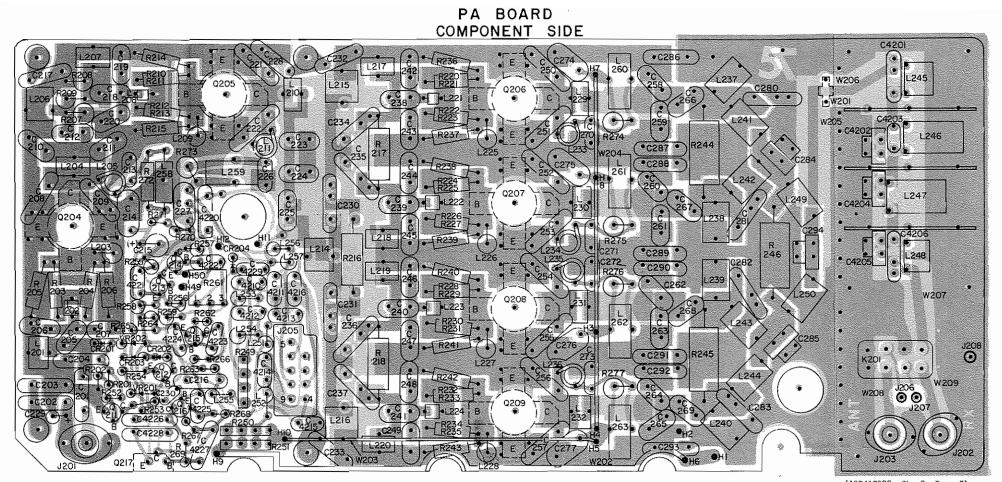
FOR Q212,Q213,Q214,

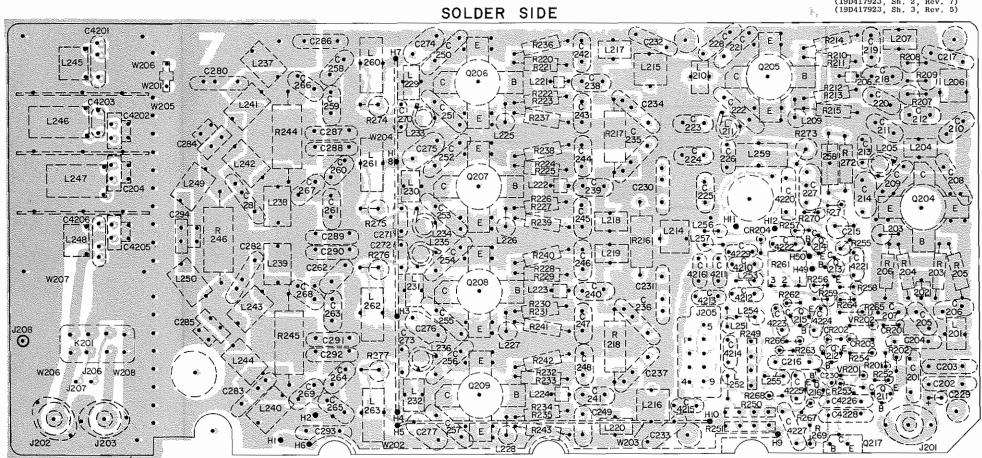


IN-LINE TRIANGULAR
VIEW FROM LEAD END

NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

(19R622110, Rev. 7)





rmbol	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
15	19A700113P47	Composition: 220 ohms ±5%, 1/2 w.	R136	19A700113P63	Composition; 1K ohms 15%, 1/2 w.	T104L*	19D416335G20	Coil,
+6	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.	R137	19A700113P37	Composition: 33 ohms ±5%, 1/2 w.			In REV & earlier;
17*	3R77P153K	Composition: 15K ohms ±10%, 1/2 w. Deleted by	R138	3R77P181K	Composition: 180 ohms ±10%, 1/2 w.		19D416635G13	Coil. Includes:
		REV H.	R139	19A700113P41	Composition: 120 ohms £5%, 1/2 w.		5493185P13	Tuning slug.
·7LL*	3R77P203J	Composition: 20K ohms ±5%, 1/2 w.	R140	19A700113P23	Composition: 22 ohms ±5%, 1/2 w.	T104M*	19D416635G21	Coil.
	3R77P303J	In REV H: Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	R141	19A700113P35	Composition: 68 ohms ±5%, 1/2 w.			In REV E & earlier;
7L	19A700113P91	Composition: 15K ohms ±5%, 1/2 w. Added by REV H.	R142	19A700113P23	Composition: 22 ohms ±5%, 1/2 w.		19D416635G5	Coxl. Includes:
7 L 7 L	19A700113P91	Composition; 15K ohms ±5%, 1/2 w.	R143LL	3R77P101K	Composition 100 ohms ±10%, 1/2 w.		5493185P13	Tuning slug.
7H	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	R143L	3R77P101K	Composition: 100 ohms ±10%, 1/2 w.	T104H*	19D416335G22	Coil.
8	3R77P474K	Composition: 470K ohms ±10%, 1/2 w.	R143M*	19A700113P19	Composition: 15 ohms ±5%, 1/2 w.			In REV E α earlier;
9	3R77P104K	Composition: 100K ohms ±10%, 1/2 w.			In REV G & earlier:		19D416635G5	Coll. Includes:
0	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.		3R77P820K	Composition: 82 ohms ±10%, 1/2 w.		5493185P13	Tuning slug,
1	19A700113P36	Composition: 75 ohms ±5%, 1/2 w.	R143H	19A700113P37	Composition: 82 ohms ±5%, 1/2 w.	T105LL	19D416635G13	Coil. Includes:
2	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R14414L	19A700113P19	Composition: 15 ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
3	19A700113P75	Composition: 3.3K ohms ±5%, 1/2 w.	R144L	19A700113P19	Composition: 15 ohms ±5%, 1/2 w.	T105L	19D416635G13	Coll. Includes:
4	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	R144M	19A700113P15	Composition; 10 ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
5	3R77P473K	Composition: 47K ohms ±10%, 1/2 w.	R144H	19A700113P15	Composition; 10 ohms ±5%, 1/2 w.	T105M	19D416635G5	Coil, Includes:
6	19A700113P57	Composition: 560 ohms ±5%, 1/2 w.	R145	19A700113P99	Composition: 33K ohms ±5%, 1/2 w.		5493185Pl3	Tuning slug.
7	19A700113P61	Composition: 820 ohms ±5%, 1/2 w.	R146	19A700113P107	Composition: 68K ohms ±5%, 1/2 w.	T105H	19D416635G5	Coll. Includes;
8	3R77P222K	Composition: 2.2K ohms ±10%, 1/2 w.	R147 thru	19A700113P99	Composition: 33K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
9	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R150			T106LL	19D416635G14	Coil. Includes:
0	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	R151	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
1	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	R152	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.	T106L	19D416635G14	Coil. Includes:
2*	3R77P153K	Composition: 15% ohms ±10%, 1/2 w. Deleted by	R153 and	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
		REV H.	R154			T106M	19D416635G6 5493185P13	Coil. Includes: Tuning slug.
2i.i.*	3R77P303J	Composition: 20K ohms ±5%, 1/2 w.			TRANSFORMERS			
		In REV H:	Tiolul	19D416635G10	Coil. Includes:	Т106Н	19D413635G6	Coil, includes:
	3R77P303J	Composition: 30K ohms ±5%, 1/2 w. Added by REV H.		5493185P13	Tuning slug.		5493185P13	Tuning slug.
2L	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	TiolL	19D416535G10	Coil. Includes:	T107LL	19D416635G15	Coil. Includes:
2 M	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.		5493185P13	Tuning slug.
2H	19A700113P91	Composition: 15% ohms ±5%, 1/2 w.	TlOLM	19D416635G2	Coil. Includes:	T107L	19D416335G15	Coil. Includes:
3*	3R77P153K	Composition; 15K ohms ±10%, 1/2 w. Deleted by REV H.		5493185P13	Tuning slug.		5493185P13	Tuning slug.
3LL*	3R77P2O3J	Composition: 20K ohms ±5%, 1/2 w.	TlOlH	19D416635G2	Coil. Includes:	T107M	19D416635G7	Coil. Includes:
31111-	3R77F2030	In REV H:		5493185Pl3	Tuning slug,	m1 0mu	5493185P13	Tuning slug. Coil. Includes:
	3R77P303J	Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	T102LL	19D416635G11	Coil. Includes:	T107H	19D416635G7 5493185P13	Tuning slug.
3L	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.	T108LL	19D416635G16	Coil. Includes:
3 M	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	T102L	19D416635G11	Coil. Includes:	1100111	5493185P13	Tuning slug.
зн	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.	T108L	19D416635G16	Coil. Includes:
A	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	T102M	19D416635G3	Coil, Includes:		5493185P13	Tuning slug.
.5	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.	T108M	19D416335G8	Coil. Includes:
:6*	3R77P431J	Composition: 430 ohms ±5%, 1/2 w.	T102H	19D416635G3	Coil, Includes:		5493185P13	Tuning slug.
		In REV D α earlier;	m1	5493185P13	Tuning slug.	т108Н	19D416635G8	Coil. Includes:
	3R77P391K	Composition: 390 ohms ±10%, 1/2 w.	T103LL	19D416635G12	Coil. Includes:		5493185Pl3	Tuning slug.
:7	19B209358P106	Variable, carbon film: approx 300 to 10,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.	T103L	5493185P13 19D416635G12	Tuning slug. Coil. Includes:			
:8	19B209358P108	Variable, carbon film; approx 2K to 50K ohms	11032	5493185Pl3	Tuning slug.	43.03	10 - 11 694201	Digital, High Speed TTL: Dual J-K Master-Slave
.		±10%, 0.25 w; sim to CTS Type x-201.	T103M	19D416635G4	Coil. Includes:	U101	19A116842P1	Flip Flop; sim to S#54H73N.
!9	19A700113P36	Composition: 75 ohms ±5%, 1/2 w.		5493185P13	Tuning slug.	U102	19D416542G2	Transmitter, Audio.
10	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	T103H	19D416635G4	Coil. Includes:			yoltage regulators
31	19A700113P75	Composition: 3.3K obms ±5%, 1/2 w.		5493185P13	Tuning slug.	VRIOL	4036887P56	Zener: 500 mW, 5.0 v. nominal.
32	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	T1041.L.*	19D416635G19	Coll.			
33	3R77P473K	Composition: 47K ohms ±10%, 1/2 w.			In REV E & earlier;			
34	19A700113P57	Composition: 560 ohms ±5%, 1/2 w. Composition: 22K ohms ±5%, 1/2 w.		19D416635G13	Coil. Includes:			
35	19A700113P95	Composit cions and ones tool at a se		5493185P13	Tuning slug.			
			-					

SYMBOL	GE PART NO.	DESCRIPTION
XY101 thru XY108	19a701785P1	NOTE: when reordering, specify quantity.  Contact, electrical.
	19A121252P1 19A129424G2 4036555P1 4029006P3	Heat sink. (Used with Q109).  Can. (Used with T101-T108 & L101-L103).  Insulator, washer: nylon. (Used with Q109).  Clip, compression: 375 x 0.19 x .02 inches; sim to Tinnerman Products C5426-014-24. (Used with Q109).
		ASSOCIATED ASSEMBLIES
Yl01 thru Yl08	19A129393G13	Compensated: 2 PPM, 25-50 MHz.
Y101 thru Y108	19A129393G16	Externally Compensated: 5 PPM, 25-50 MHz.

#### **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

#### 19D416659G1-G8

- REV. A To incorporate an improved transistor. Changed Q107.
- REV. B To increase power output. Changed C146\* and added C156.
- REV. C To increase drive to modulator. Changed Q101 and R102.
- REV. D To provide RF bypassing on unused frequency selection leads. Added C157 thru C163.
- REV. E To increase audio sensitivity. Changed R126.
- REV. F To eliminate possible shorting of shield to wire runs on printed wire board. Changed TlO4LL, TLO4L, TlO4M and TlO4H. Deleted shield (198219619P1), Cl29LL, Cl29L, Cl29M and Cl29H.

#### 19D416659G4 & G8

REV. G - To improve multi-frequency spread performance in cold temperatures. Changed Cl30H.

#### 19D416659G3 & G7

- REV. G To improve multi-frequency spread performance with high humidity. Changed Cl30.
- REV. H To improve spurious and stability performance. Physically changed (swapped) positions of L201 and C205.
- REV. G 19D416659G1, G2, G5, G6
- REV. J 19D416659G3, G7
- REV. H 19D416659G4, G8
  - To increase exciter output. Changed Q109.

#### REV. H - 19D416659G1. G5

To increase Channel Guard deviation at the low end of the split. Deleted R107, R122 and R123. Added R107LL, R122LL and R123LL.

#### REV. J - 19D416659G1, G5

To meet symmetry specs. Changed R107LL, R122LL and R123LL.

	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYM
-												-	
	C125M	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.	C137M	19A700013P8	Phenolic: 0.39 pf ±5%, 500 YDCW.	J103	19B219374G1	Connector, Includes:	R105	19A700113P47	Composition: 220 ohms ±5%, 1/2 w.	R136
	C125H	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCw, temp coef -80 PPM.	С137Н	19A700013P8	Phenolic: 0.39 pf ±5%, 500 VDCw.		19A116651P1	Contact, electrical: Sim to Malco XO-2864.	R106	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.	R137
	C12614	5491601P124	Phenolic: 1.8 pf ±5%, 500 YDCW.	C138LL	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.				R107*	3R77P153K	Composition: 15K ohms ±10%, 1/2 w. Deleted by REV H.	8138
- 1	C126L	5491601P124	Phenolic: 1.8 pf ±5%, 500 VDCW.	C138L	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCm, temp	T1011T	19D416635G9	Coil.	R10711.	3R77P203J	Composition: 20K ohms ±5%, 1/2 w.	R139
	C126M	19A700013P14	Phenolic: 1.2 pf ±5%, 500 VDCW.	C138M	5496219P242	coef -80 PPM.  Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef	Lioit	19D416635G17	Coil.	)		In REV H:	R140 R141
	C126H	19A700013P14	Phenolic: 1.2 pf ±5%, 500 VDCw.	C138H	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCw, temp	T107H T107W	19D416635G1	Coil.		3R77P303J	Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	R142
-	C127LL	5496219P262	Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef -80 PPM.			coef -80 PPM.	L102LL	19D416635G18 19D416635G9	Coil.	R107L R107M	19A700113P91 19A700113P91	Composition: 15K ohms ±5%, 1/2 w.  Composition: 15K ohms ±5%, 1/2 w.	R143
-     ,	C127L	5496219P258	Ceramic disc: 62 pf ±5%, 500 VDCh, temp coef	C139	19A116080P107	Polyester: 0.1 µf ±20%, 50 VDCh.	L102L	19D416635G17	Coil.	R107H	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	K143
	-10""	640,1010,000	-80 PPM.	C140	19A116d55P19	Ceramic disc: 1000 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.	L102M	19D416635G1	Coil.	R108	3R77P474K	Composition: 470K ohms ±10%, 1/2 w.	R143
] '	C127M	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCh, temp coef -80 PPM.	C1411.d.	5490008P127	Silver mica: 100 pf ±10%, 500 VDCh; sim to flectro Motive Type DM-15.	L102H	19D416635G18	Coil.	R109	3R77P104K	Composition: 190% ohms ±10%, 1/2 w.	
-     '	С127Н	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCm, temp coef ~80 PPM.	C141L	5490008P125	Silver mica: 82 pf ±10%, 500 VDCW; sim to	L10314	19D416635G9	Coil.	R110	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	
	C128	19A116080Pl	Polyester: 0.01 µf ±20%, 50 VDCW.			Electro Motive Type DM-15.	L103L	19D416635G17	Coil.	Rlll	19A700113P3d	Composition: 75 ohms ±5%, 1/2 w.	R143
	C129LL*	5496219P255	Ceramic disc: 47 pf ±5%, 500 VDCw, temp coef	C1416#	5490008P131	Silver mica: 150 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	TJO3W	19D416635G1	Coil.	R112	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R144
	C129L*	5496219P251	-80 PPM. Deleted by REV F.  Ceramic disc: 33 pf ±5%, 500 VDCm, temp coef			In REV G & earlier;	L103H	19D416635G18	CO11.	R113	19A700113P75	Composition: 3.3K ohms ±5%, 1/2 w.	R144 R144
	C129L*	24962199201	-80 PPM. Deleted by REV F.	\ \ \	5490008P123	Silver mica: 68 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	L104LL	19A700000P16 19A700000P15	Choke, RF: 2.7 µh ±10%, 1.20 ohms DC res max.	R114	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	R144
	C129M*	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCw, temp coef -80 PPM. Deleted by REV F.	C141H	5490008P127	Silver mica: 100 pf ±10%, 500 VDCW; sim to	L104M*	19A700000P6	Choke, RF: 2.20 µh ±10%, 0.97 ohms DC res max.  Choke, RF: 0.33 µh ±10%, 0.07 ohms DC res max.	R115 R116	3R77P473K 19A700113P57	Composition: 47K ohms ±10%, 1/2 w.  Composition: 560 ohms ±5%, 1/2 w.	R145
	C129H*	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCm, temp coef			Electro Motive Type DM-15.	22072	25111 0000000	In REV G & earlier:	R117	19A700113P61	Composition: 820 ohms ±5%, 1/2 w.	R146
	_,,_,	10.0001000	-80 PPM. Deleted by REV F.	C142LL	5490008P27	Silver mica: 100 pf ±50%, 50 VDCW; sim to Electro Motive Type DM-15.		7488079P7	Choke, RF: 1.50 µh ±10%, 0.50 ohms DC res max;	R118	3R77P222K	Composition: 2.2K ohms ±10%, 1/2 w.	R147
- 1 1	C130T	19A700013P9 5491601P110	Phenolic: 0.47 pf ±5%, 500 VDC%.  Phenolic: 0.36 pf ±5%, 500 VDC%.	C142L	5490008P25	Silver mica: 82 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.		104700000014	sim to Jeffers 4411-10K.	R119	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R150
- 11	C130M*	19A700013P7	Phenolic: 0.33 pf ±5%, 500 VDCh.	C142M	5490008P25	Silver mica: 82 pf ±5%, 500 VDCH; sim to Electro	L104H L105LL	19A700000P14 19A700000P12	Choke, RF: 1.5 µh ±10%, 0.485 chms DC res max.  Choke, RF: 1.0 µh ±10%, 0.29 chms DC res max.	R120	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	R151
	01002		In REV F & earlier:			Motive Type DM-15.	L105L	19A700000P10	Choke, RF: 0.68 µh ±10%, 0.15 ohms DC res max.	R121	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	R152
11	ļ	5491601P107	Phenolic: 0.27 pf ±5%, 500 VDCw.	C142H	5490008P24	Silver mica: 75 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	1105M	19A700000P8	Choke, RF: 0.47 µh ±10%, 0.09 ohms DC res max.	R122*	3R77P153K	Composition: 15K ohms ±10%, 1/2 w. Deleted by REV H.	R153 and R154
	C130H*	19A700013P6	Phenolic: 0.27 pf ±5%, 500 VDCW.	C143	19A11G163P5	Variable; approx 5 to 60 pf, 50 VDCW; sim to Amperex 2222-809-08003.	T102H	19A700000P6	Choke, RF: 0.33 μh ±10%, 0.07 ohms DC res max.	R122LL*	3R77P303J	Composition: 20K ohms ±5%, 1/2 w.	h
			In REV F & earlier:	C144	5494481P105	Ceramic disc: 330 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	L106 and L107	19A700000P23	Choke, RF: 10.0 µh ±10%, 0.605 ohms DC res max.			In REV H:	T101
		5491601P105	Phenolic: 0.22 pf ±5%, 500 VDC%.	C145	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCh.	F108	19A700000P14	Choke, RF: 1.50 µh ±10%, 0.48 ohms DC res max.	R122L	3R77P303J 19A700113P91	Composition: 30K ohms ±5%, 1/2 w. Added by REV H. Composition: 15K ohms ±5%, 1/2 w.	1 1101
	C1311.1.	5496219P255	Ceramic disc: 47 pf ±5%, 500 VDCW, temp conf-80 PPM.	C146*	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp coef ~80 PPM. Added by REV B.			' '	R122M	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	110,
	CISIL	5496219P251	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -80 PPM.	C146LL*	19A116656P12J8	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.	l			R122H	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	TIO
- 11,	C131M	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCw, temp coef	C146L*	19A116656P12J8	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.	P902	19B219594P2	Includes: Contact strip: 8 pins.	R123*	3R77P153K	Composition; 15K ohms ±10%, 1/2 w. Deleted by	i I - I
- 11			-80 PPM.	C146M*	19A116656P13J8	Ceramic: 13 pf, ±5%, 0 PPM. Deleted by REV B.	ļ	19B219594P3	Contact strip: 9 pins.	R123LL*	3R77P2O3J	REV H.  Composition: 20K ohms ±5%, 1/2 w.	110:
-	С131Н	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef ~80 PPM.	C146H*	19Al16d56P12J8	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.			1	RIZSIA	JA7112050	In REV H:	ıl I
	C132	19Al16080Pl	Polyester: 0.01 µf ±20%, 50 VDCW.	C147	19All6080Pl07	Polyester: 0.1 µf ±20%, 50 VDCW.	0101		TANASISTORS		3R77P303J	Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	T102
	and C133			C148	5494481P105	Ceramic disc: 330 pf ±20%, 1000 VDCw; sim to RMC Type JF Discap.	Q101*	19A115330P1	Silicon, NPN. In REV C α earlier:	R123L	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	
	C13411	5496219P243	Ceramic disc; 13 pf ±5%, 500 VDCW, temp coef ~80 PPM.	C149	5496267P10	Tantalum: 22 µf ±20%, 15 VDCw; sim to Sprague		19A115910P1	Silicon, NPN; sim to Type 2N3904.	R123M	19A700113₽91	Composition: 15K ohms ±5%, 1/2 w.	T10:
,	C134L	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCw, temp	0350	E404947014	Type 150D.  Tantalum: 15 \( \mu f \pm 20\) \( \pi \), 20 \( \mathrm{VDCW} \); \( \sim \) to \( \mathrm{Sprague} \)	Q102	19A115330P1	Silicon, NPN.	R123H	19A700113P91	Composition: 15% ohms ±5%, 1/2 w.	T10
	C134M	5496219P242	coef -80 PPM.  Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef	C150	5496267P14	Type 150D.	thru Q106			R124	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	
	C134W	04902197242	-80 PPM.	C151	5494481P105	Ceramic disc; 330 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	Q107*	19A115328P1	Silicon, NPN.	R125	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.	T10
	C134H	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCm, temp coef -80 PPM.	C152	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCm.			Earlier than REV A:	R126*	3R77P431J	Composition: 430 ohms ±5%, 1/2 w.  In REV D & earlier:	
	C135 <i>L</i> .L.	19A700013P11	Phenolic: 0.68 pf ±5%, 500 VDCW.	thru C155				19A115330P1	Silicon, NPN.	ł	3R77P391K	Composition: 390 ohms ±10%, 1/2 w.	. T10
	Cl35L	5491601P114	Phenolic: 0.51 pf ±5%, 500 VDCW.	C156*	19A116867P1	Variable, ceramic: 2.5-6 pf, +50% -10%, 160 VDCW; sim to 7-S-TRIKO-02. Added by REV B.	Q108	19A115328P1	Silicon, NPN.	R127	19B209358Pl06	Variable, carbon film; approx 300 to 10,000 ohms	
	C135M	19A700013P10	Phenolic: 0.56 pf ±5%, 500 VDCW.	C157*	19A116080P1	Polyoster: 0.01 µf ±20%, 50 VDCm. Added by REV C	Q109*	19A116868P1	Silicon, NPN; sim to Type 2N4427.  In Gl.G2.G5.G6 of REV F & earlier;	n100	1000000000000	±10%, 0.25 w; sim to CTS Type X-201.  Variable, carbon film: approx 2K to 50K ohms	TlO
	C135H	19A700013P9	Phenolic: 0.47 pf ±5%, 500 VDCW.	thru C163*					In Gl,G2,G5,G6 of REV F & earlier: In G3,G7 of REV H & earlier: In G4,G8 of REV G & earlier:	R128	19B209358P108	±10%, 0.25 w; sim to CTS Type X-201.	T10
	C136IT	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.			DIODES AND RECTIFIERS		19A115329P2	Silicon, NPN.	R129	19A700113P36	Composition: 75 ohms ±5%, 1/2 w.	
	C136L	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCw, temp coef -80 PPM.	CR101 thru	19A115250P1	Silicon, fast recovery, 225 ma, 50 PIV.				R130	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	T10
	C136M	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCh, temp coef	CR106			R101	19A700113P57	Composition: 560 ohms ±5%, 1/2 w.	R131	19A700113P75	Composition: 3.3K ohms ±5%, 1/2 w.  Composition: 510 ohms ±5%, 1/2 w.	
			-80 PPM.	CV101 thru	5495769P12	Silicon, capacitive.	R102*	19A700113P57	Composition: 6.8K ohms ±5%, 1/4 w.	R132 R133	3R77P511J 3R77P473K	Composition: 47K ohms ±10%, 1/2 w.	TIC
	C136H	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	CV103		JACKS AND RECEPTACLES			In REV C & earlier:	R133	19A700113P57	Composition: 560 ohms ±5%, 1/2 w.	
	C137LL	5491601P114	Phenolic: 0.51 pf ±5%, 500 VDCw.	J101	19A130924G1	Connector, receptacles; sim to Cinch 14H11613.		3R77P393K	Composition: 39K ohms ±10%, 1/2 w.	R135	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	
	C137L	5491601P114	Phenolic: 0.51 pf ±5%, 500 VDCW.				R103	19A700113P55	Composition: 470 ohms ±5%, 1/2 w.				
							R104	19A700113P35	Composition: 68 ohms ±5%, 1/2 w.				
∟ GES													

NGES

#### PARTS LIST

LB14440L

25-50 MHz EXCITER 19D416659G1-G8

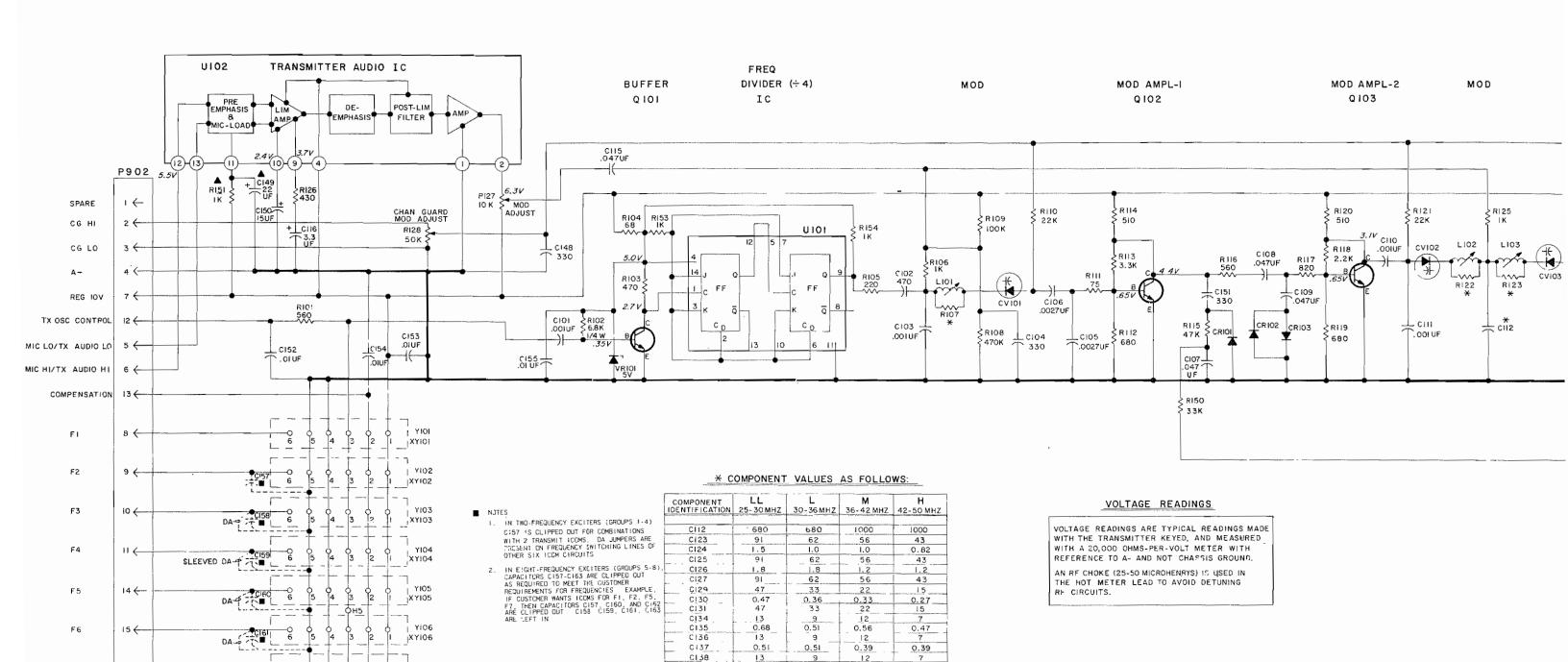
SYMBOL	GE PART NO.	DESCRIPTION
		19D416659G1 2 FREQ 25-30 MHz (LL) 19D416659G2 2 FREQ 30-36 MHz (L) 19D416659G3 2 FREQ 36-42 MHz (M) 19D416659G5 8 FREQ 25-30 MHz (L) 19D416659G5 8 FREQ 25-30 MHz (L) 19D416659G7 8 FREQ 36-42 MHz (M) 19D416659G8 8 FREQ 36-42 MHz (M)
C101	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C102	19A116655P13	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C103	19All6d55P19	Ceramic disc: 1000 pf ±20%, 1000 VDCm; sim to RMC Type JF Discap.
C104	5494481P105	Ceramic disc: 330 pf ±20%, 1000 VDCm; sim to
C105 and C106	19A116655P21	RMC Type JF Discap.  Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C105 C107 thru C109	19A116080P105	Polyester: 0.047 µf ±10%, 50 VDCw.
C110 and C111	19A116655P19	Ceramic disc; 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
•		
C112LL	4029003P104	Silver mica: 680 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-20.
C112L	4029003P104	Silver mica: 680 pf ±10%, 500 VDCN; sim to Electro Motive Type DM-20.
C112M	5493367P1000K	Mica: 1000 pf ±10%, 100 YDCW; sim to Electro Motive Type DM-20.
С112Н	5493367P1000K	Mica: 1000 pf ±10%, 100 VDCm; sim to Electro Motive Type DM-20.
C113 and C114	19A116655P21	Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C115	19A116080P105	Polyester: 0.047 µf ±10%, 50 VDCm.
C116	5496267 <b>P</b> 9	Tantalum: 3.3 µf ±20%, 15 VDCw; sim to Sprague Type 150D.
C117 thru C119	19116080Pl05	Polyester: 0.047 µf ±10%, 50 VDCW.
C120	5490008P139	Mica: 330 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.
C121 and C122	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCW.
C123LL	5496219P262	Ceramic disc: 91 pf ±5%, 500 VDCm, temp coef -80 PPM.
C123L	5496219P258	Ceramic disc: 62 pf ±5%, 500 VDCW, temp coef -80 PPM.
C123M	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.
С123Н	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCW, temp coef
C124LL	19A700013P15	-80 PPM.  Phenolic: 1.5 pf ±5%, 500 VDCW.
C124LL	19A700013P13	Phenolic: 1.0 pf ±5%, 500 VDCW.
		Phenolic: 1.0 pf ±5%, 500 VDCW.
C124M	19A700013P13	Phenolic: 0.82 pf ±5%, 500 VDCW.
C124H	19A700013P12	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef
C1251.L	5496219P262	-80 PPM.
C125L	5496219P258	Ceramic disc: 62 pf ±5%, 500 VDCH, temp coef -80 PPM.

SYMBOL	GE PART NO.	DESCRIPTION
C125M	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCH, temp coef -80 PPM.
С125Н	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCm, temp coef -80 PPM.
C126LL	5491601P124	Phenolic: 1.8 pf ±5%, 500 VDCW.
C126L	5491601P124	Phenolic: 1.8 pf £5%, 500 VDCW.
C126M	19A700013P14	Phenolic: 1.2 pf ±5%, 500 VDCw.
C126H	19A700013P14	Phenolic: 1.2 pf ±5%, 500 VDCW.
127LL	5496219P262	Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef -80 PPM.
127L	5496219P258	Ceramic disc: 62 pf ±5%, 500 VDCW, temp coef ~80 PPM.
2127M	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCw, temp coef -80 PPM.
:127Н	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCh, temp coef -80 PPM.
128	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCm.
129LL*	5496219P255	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef -80 PPM. Deleted by REV F.
1294*	5496219P251	Ceramic disc: 33 pf ±5%, 500 VDCH, temp coef -80 PPM. Deleted by REV F.
:129 <b>M</b> *	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCm, temp coef -80 PPM. Deleted by REV F.
129H*	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCh, temp coef -80 PPM. Deleted by REV F.
:130LL	19A700013P9	Phenolic: 0.47 pf ±5%, 500 VDCw.
:130LL	5491601P110	Phenolic: 0.36 pf ±5%, 500 VDCW.
130L 130M*	19A700013P7	Phenolic: 0.33 pf ±5%, 500 VDCW.
₹20 <b>ш</b> 4	257,0001387	In REV F & earlier:
	5491601P107	Phenolic: 0.27 pf ±5%, 500 VDCh.
130H*	19A700013P6	Phenolic: 0.27 pf ±5%, 500 VDCw.
		In REV F & earlier:
	5491601P105	Phenolic: 0.22 pf ±5%, 500 VDCW.
131TT	5496219P255	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef -80 PPM.
131T	5496219P251	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef ~80 PPM.
131M	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCw, temp coef -80 PPM.
131H	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef -80 PPM.
:132 .nd :133	19A116080P1	Polyester: 0.01 µ1 ±20%, 50 VDCh.
134LL	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.
134L	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.
134M	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCH, temp coof -80 PPM,
134н	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCh, temp
135LL	19A700013P11	coef -80 PPM.  Phenolic: 0.68 pf ±5%, 500 VDCW.
135L	5491601P114	Phenolic: 0.51 pf ±5%, 500 VDCm.
135M	19A700013P10	Phenolic: 0.56 pf ±5%, 500 VDCw.
135H	19A700013P9	Phenolic: 0.47 pf ±5%, 500 VDCW.
13611	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM,
	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCw, temp
:136L	0.000.00.000	coef -80 PPM,
2136L 2136K	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCh, temp coef
		Ceramic disc: 12 pf ±5%, 500 VDC%, temp coef -80 PPM.  Ceramic disc: 7.0 pf ±0.25 pf, 500 VDC%, temp
2136M	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCm, temp coef -80 PPM.

SYMBOL	GE PART NO.	DESCRIPTION	SYME
C137M	19A700013P8	Phenolic: 0.39 pf ±5%, 500 VDCh.	J103
C137H	19A700013P8	Phenolic: 0.39 pf ±5%, 500 VDCw.	
C138TT	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef	
C138F	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCh, temp coef -80 PPM.	L101L
CT38W	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCw, temp coef	LIOIM
С138н	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCh, temp coef -80 PPM.	TIOTH
C139	19A116080P107	Polyester: 0.1 µf ±20%, 50 VDCh.	1.10214
C140	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.	L102i
C1411.L	5490008P127	Silver mica: 100 pf ±10%, 500 VDCh; sim to Electro Motive Type DM-15.	£102M £102H
C141L	5490008P125	Silver mica: 82 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	F103FT
C141M*	5490008P131	Silver mica: 150 pf ±10%, 500 VDCb; sim to Electro Motive Type DM-15.	L103L
l		In REV G & earlier;	L103H
	5490008P123	Silver mica: 68 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	L10414
C14lH	5490008P127	Silver mica: 100 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	L104L
C142LL	5490008P27	Silver mica: 100 pf ±50%, 50 VDCW; sim to Electro Motive Type DM-15.	
C142L	5490008P25	Silver mica: 82 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
C142M	5490008P25	Silver mica: 82 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.	L104H L105LL
C142H	5490008P24	Silver mica: 75 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	L105L
			aroun
C143	19A116163P5	Variable: approx 5 to 60 pf, 50 VDCW; sim to Amperex 2222-809-08003.	L105H
C144	5494481P105	Ceramic disc: 330 pf ±20%, l000 VDCW; sim to RMC Type JF Discap.	L106 and
C145	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCh.	L107
C146*	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM. Added by REV B.	1.108
C146id.*	19a116656P12J8	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.	P902
C146L*	19A116656P12J8	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.	1002
C146M*	19A116656P13J8	Ceramic: 13 pf, ±5%, 0 PPM. Deleted by REV B.	
C146H*	19A116356P12J8	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.	
C147	19A116080P107	Polyester: 0.1 µf ±20%, 50 VDCW.  Ceramic disc: 330 pf ±20%, 1000 VDCW; sim to	Q101*
C148	5494481P105	RMC Type JF Discap.	1
C149	5496267P10	Tantalum: 22 µf ±20%, 15 VDCh; sim to Sprague Type 150D.	Q102
C150	5496267P14	Tantalum: 15 µf ±20%, 20 VDCW; sim to Sprague Type 150D.	thru Q106
C151	5494481P105	Ceramic disc: 330 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	Q107*
thru C155	19A116080P1	Polyester; 0.01 µf ±20%, 50 VDCm.	
C156*	19Al16867Pl	Variable, ceramic: 2.5-6 pf, +50% -10%, 160 VDCw; sim to 7-S-TRIKO-02. Added by REV B.	Q108 Q109*
C157* thru C163*	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCm. Added by REV C	9109*
CR101	19A115250₽1	DIODES AND RECTIFIERS Silicon, fast recovery, 225 ma, 50 PIV.	
thru CR106			
CV101 thru	5495769P12	Silicon, capacitive.	R101 R102+
CA103		JACKS AND RECEPTACLES	
J101	19A130924G1	Connector, receptacles; sim to Cinch 14H11613.	
			R103 R104

SYMBOL	GE PART NO.	DESCRIPTION
J103	198219374G1	Connector, includes;
	19All6651Pl	Contact, electrical: sim to Malco XO-28
المالك	19D416635G9	Coil.
L101L	19D416635G17	Coil.
L101M	19D416635G1	Coil.
.101н	19D416635G18	Coil.
L102LL	19D4 16635G9	Coil.
1021	19D416635G17	Coil,
.102M	19D416635G1	Coil.
J102H	19D416635G18	Coil,
10314	19D416635G9	Coil.
103L	19D416635G17	Coil.
103M	19D4 16635G1	Coil.
103H	19D416635G18	Coil.
10414	19A700000P16	Choke, RF: 2.7 µh ±10%, 1.20 ohms DC res
.104L .104M*	19A700000P15	Choke, RF: 2.20 μh ±10%, 0.97 ohms DC re
110.7 W.+	19A700000P6	Choke, RF: 0.33 µh ±10%, 0.07 ohms DC rc
	7488079P7	In REV G α earlier:  Choke, RF: 1.50 μh ±10%, 0.50 ohms DC re sim to Jeffers 4411-10K.
104н	19A700000P14	Choke, RF: 1.5 µh ±10%, 0.485 ohms DC re
10511	19A700000P12	Choke, RF: 1.0 µh ±10%, 0.29 ohms DC res
1051	19A700000P10	Choke, RF: 0.68 µh ±10%, 0.15 ohms DC re
105M	19А700000Р8	Choke, RF: 0.47 µh ±10%, 0.09 ohms DC re
105H 106 nd	19A700000P6	Choke, RF: 0.33 μh ±10%, 0.07 ohms DC re Choke, RF: 10.0 μh ±10%, 0.605 ohms DC r
107	19A700000P14	Choke, RF: 1.50 µh ±10%, 0.48 ohms DC re
902	ļ	Includes;
	19B219594P2	Contact strip: 8 pins.
	19B219594P3	Contact strip: 9 pins.
101*	19A115330P1	Silicon, NPN.
	}	In REV C & earlier:
	19A115910P1	Silicon, NPN; sim to Type 2N3904.
102 hru 106	19A115330P1	Silicon, NPN.
107*	19A115328P1	Silicon, NPN. Earlier than REV A:
	19A115330Pl	Silicon, NPN.
108	19A115328P1	Silicon, NPN.
109*	19A116868P1	Silicon, NPN; sim to Type 2N4427.
		In Gl,G2,G5,G6 of REV F & earlier: In G3,G7 of REV H & earlier: In G4,G8 of REV G & earlier:
	19A115329P2	Silicon, NPN.
101	19A700113P57	Composition: 560 ohms ±5%, 1/2 w.
102*	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w. In REV C & earlier:
	3R77P393K	Composition: 39K ohms ±10%, 1/2 w.
103	19A700113P55	Composition: 470 ohms ±5%, 1/2 w.
104	19A700113P35	Composition: 68 ohms ±5%, 1/2 w.

7



C141

0142\_ L108

L104

L105

R143

R144

R107

R122

R123

100

100 39

2.7

100

20K

20K

20K

15

2.2

0.68

100

15K

15K

15K

150

0.47

10

15 K

15 K

15K

100

39

0.33

10

.....15 K

15 K

15K

# **SCHEMATIC DIAGRAM**

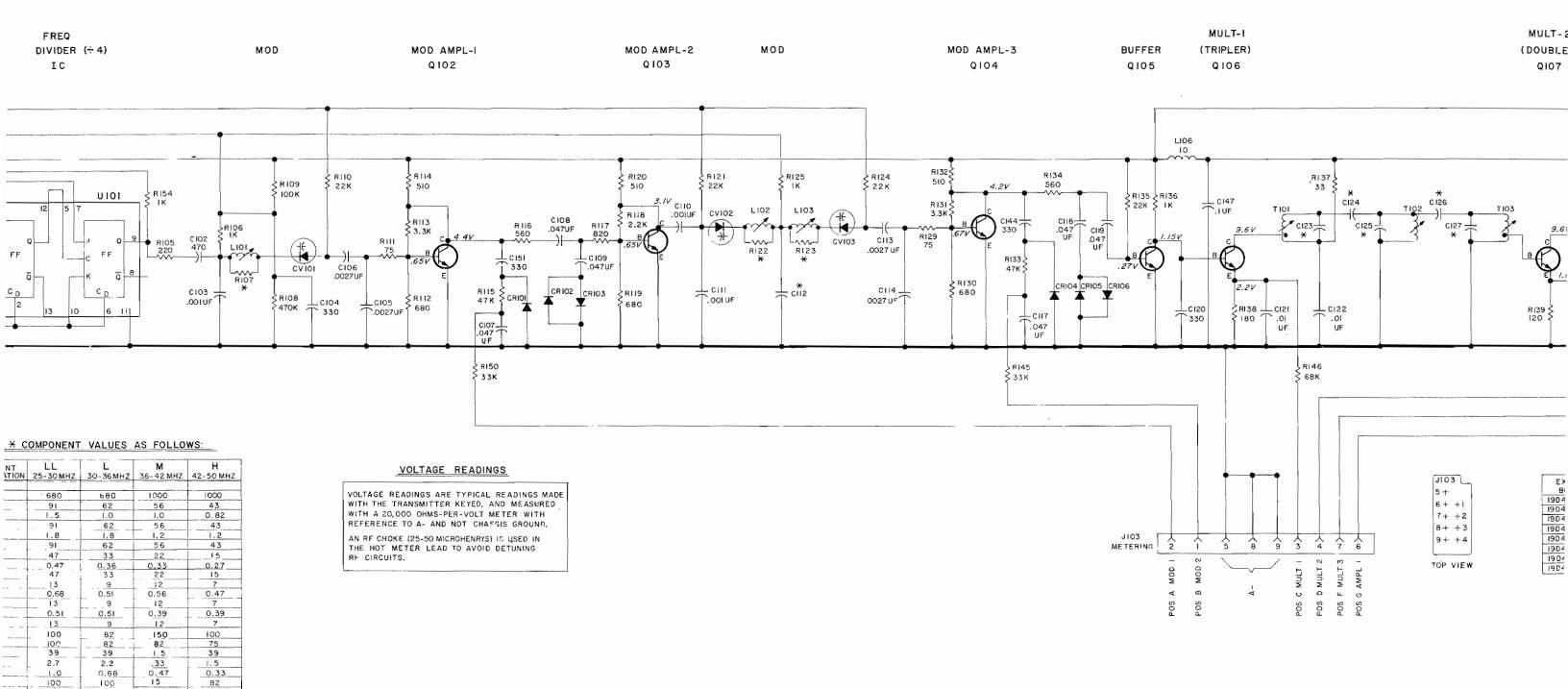
F8

25-50 MHz, EXCITER BOARD 19D416659G1-G8

Y107

80IY

14 Issue 6



1<u>5</u> \_\_20K

20K

20K

15K

15K

15K

10 15 K

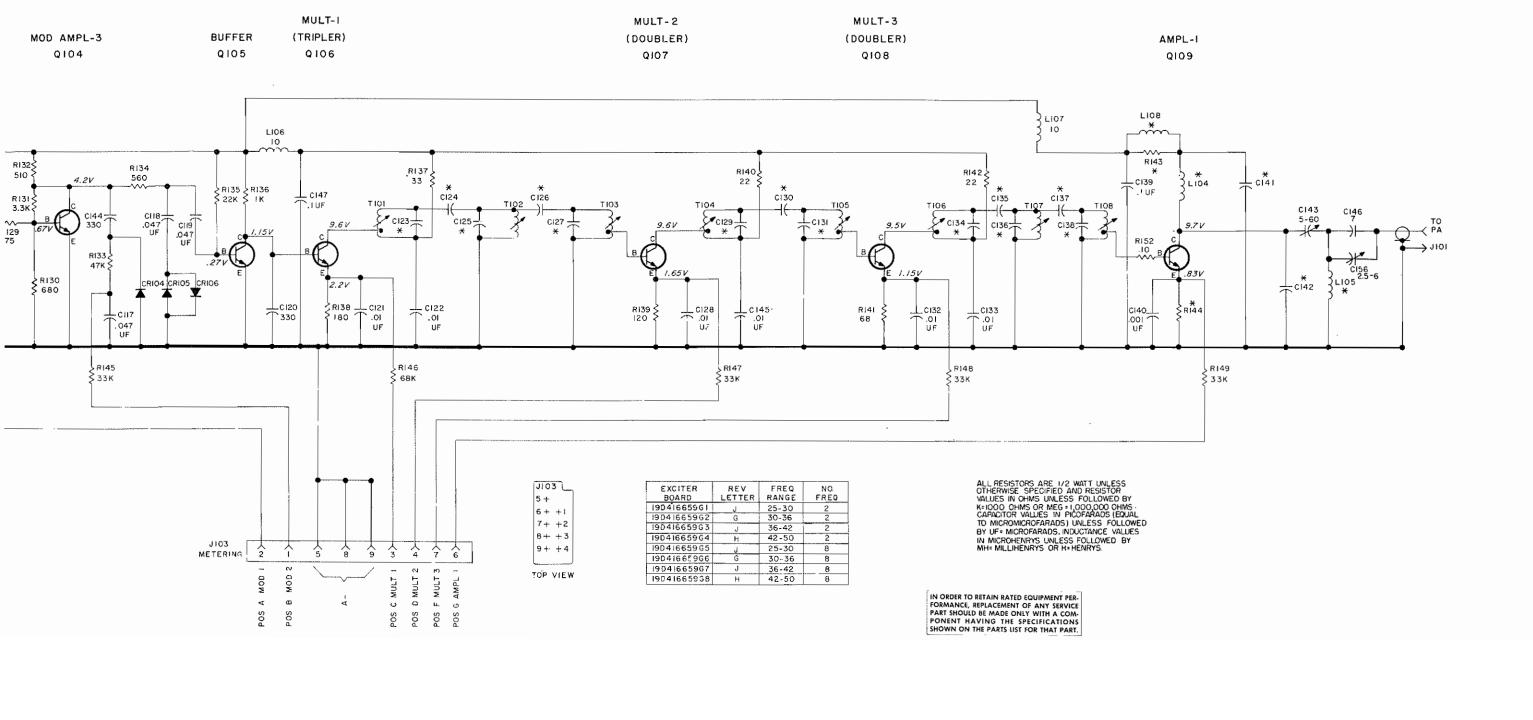
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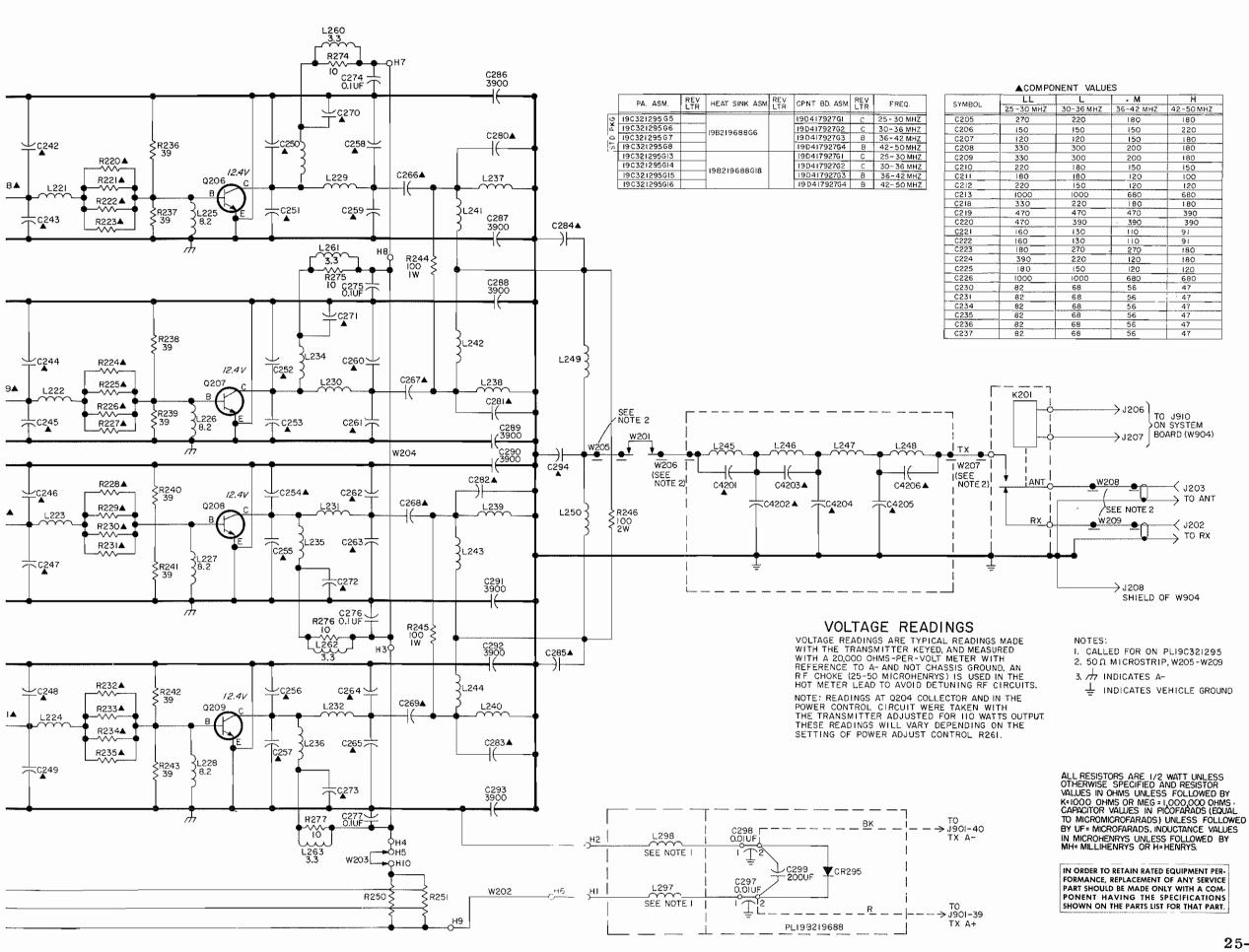
15K

15K

15 K

15K





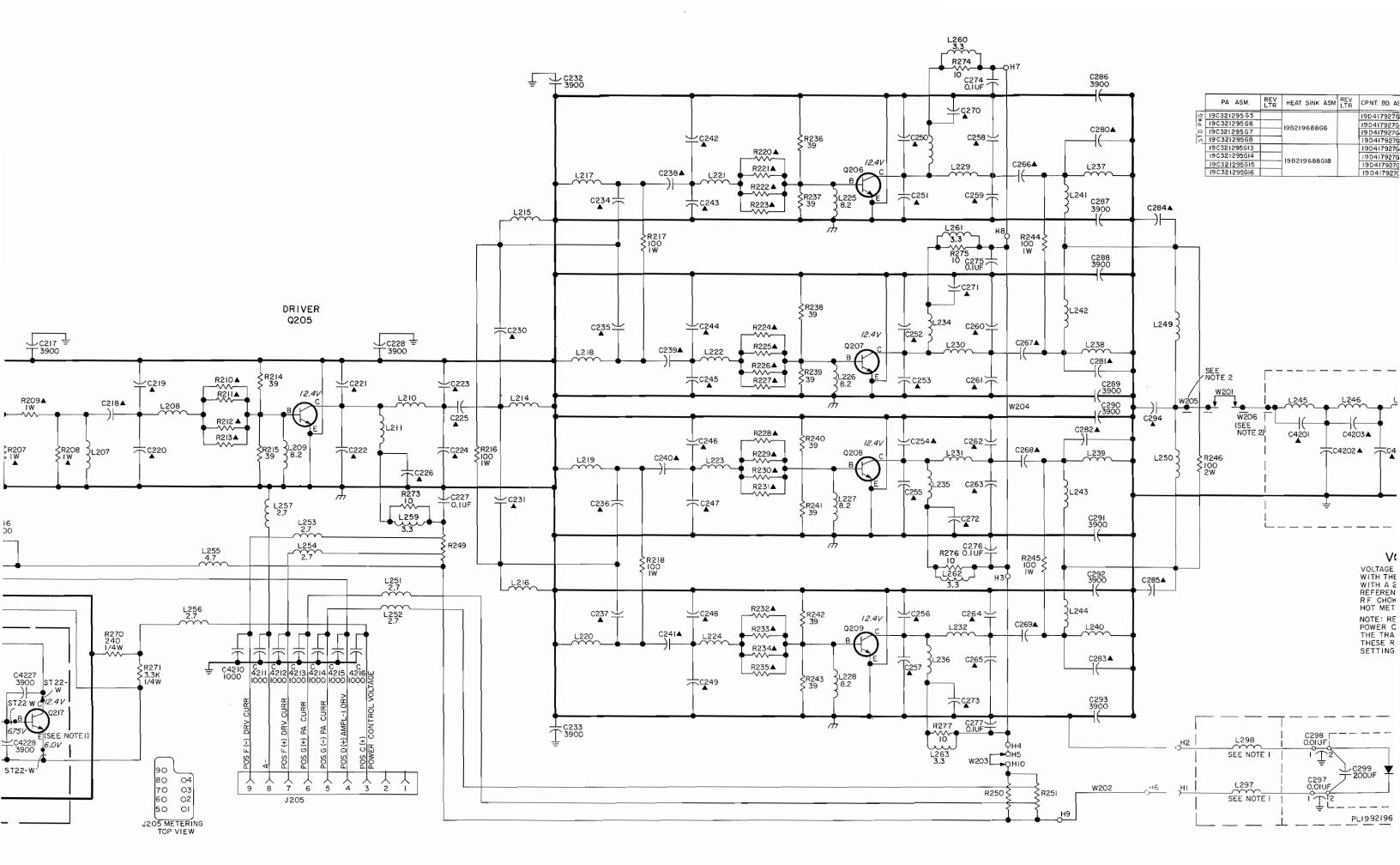
▲COMPONENT VALUES

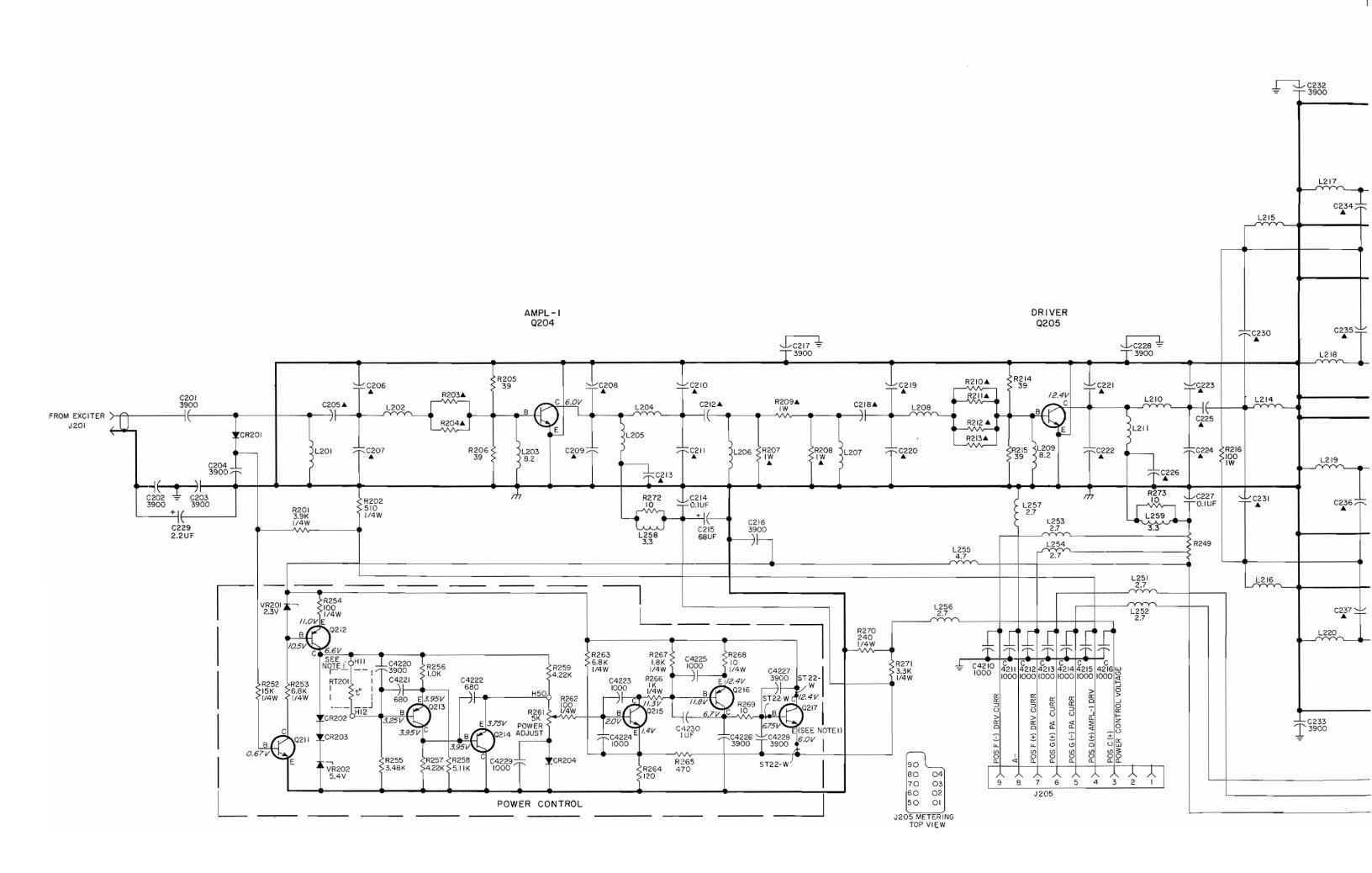
FT		PONENT VAL	UES	
SYMBOL	LL	L	M	Н
	25-30 MHZ	30-36 MHZ	36-42 MHZ	42-50 MHZ
C238	330	220	180	180
C239	330	220	180	180
C240	330	550	180	180
C241 C242	330 470	220	180	180
C243	470	470 390	390 330	390
C244	470	470	390	330 390
C245	470	390	330	330
C246	470	470	390	390
C247	470	390	330	330
C248	470	470	390	390
C249	470	390	330	330
C250	160	130	110	91
C251 C252	160	130	110	91
C253	160	130	110	91
C254	160	130	110	91
C255	160	130	110	91
C256	160	130	110	91
C257	160	130	110	91
C258	390	270	270	180
C259	180	220	120	180
C260	390	270	270	180
C261	180	220	120	180
C262	390	270	270	180
C263	180	220	120	180
C265	390	270	270	180
C266	180	220	120	180
C267	180	180	120	120
C268	180	IBO	120	120
C269	180	180	120	120
C270 .	1000	1000	680	680
C271	1000	1000	680	680
C272	1000	1000	680	680
C273	1000	1000	680	680
C280	. 82	68	56	47
C281 C282	82 82	68	56	47
C283	82	68	56	47 47
C284	240	200	56 160	140
C285	240	200	160	140
C294	160	130	110	91
C420I	91	68	56	51
C4202	110	91	68	56
C4203	15	13	12	10
C4204	140	011	91	82
C4205	150	91	82	75
C4206 R203	91	68	56	51
R204	12	10	8.2	4.7
R207	680	680	680 680	910
R208	680	680	680	910
R209	8.2	8.2	8.2	5.6
R210	6.8	3.9	2.0	1.2
R211	6.8	3.9	2.0	1.2
R212	6.8	3.9	2.0	1.2
R213	6.8	3.9	2.0	1.2
R220 R221	6.8	3.9	2,0	1.2
R222			2.0	1.2
R223	6.8 6.8	3.9	2.0	1.2
R224	6.8	3.9	2,0	1.2
R225	6.8	3.9	2.0	1.2
R226	6.8	3.9	20	1.2
R227	6.8	3.9	2.0	1.2
R228	6.8	3.9	2.0	1.2
R229	6.8	3.9	2.0	1.2
		3.9	2.0	1.2
R230	6.8			
R230 R231	6.8	3.9	2.0	1.2
R230 R231 R232	6.8 6.8	3.9 3.9	5.0	1.2
R230 R231	6.8	3.9	2.0	1.2

## SCHEMATIC DIAGRAM

25-50 MHz, 100-WATT POWER AMPLIFIER

Issue 5





#### PARTS LIST

LB14899F

25-50 MHz, 100 WATT POWER AMPLIFIER 19C321295G5-G8 19C321295G13-G16

SYMBOL	GE PART NO.	DESCRIPTION
		19C321295G5, G13 25-30 MHz (LL) 19C321295G6, G14 30-36 MHz (L) 19C321295G7, G15 36-42 MHz (M) 19C321295G8, G16 42-50 MHz (H)
L297 L298	19B219997P1 19B219997P2	Coil.
11250	100010001	
Q204	19A116965Pl	Silicon, NPN.
Q204 Q205	19A116965P1 19A134104P1	Silicon, NPN. Silicon, NPN.
thru Q209		
Q217	19A116742P1	Silicon, NPN.
		THERMISTORS
RT201	19A129379G1	Thermistor: 40K ohms ±20%, color code white; sim to Carborundum Type M0806J-5.
		POWER AMPLIFIER BOARD 19D417927G1 25-30 MHz (LL) 19D417927G2 30-36 MHz (L) 19D417927G3 36-42 MHz (N) 19D417927G4 42-50 MHz (H)
C201 thru C204	19A116655P23	Ceramic disc: 3900 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.
C2051LL	19A700105P46	Mica; 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C205L	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C205M and C205H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206LL	19A700105P38	Mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206L	19A700105P38	Mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206M	19A700105P38	Mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206H	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM=15.
C207LL and C207L	19A700105P36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C207M	19A700105P38	Mica: 150 pf ±5%, 500 VDCW; sim to Electro Notive Type DM-15.
C207H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C208LL	19All6656P330J15	
C208L	19A116656P300J15	The state of the s
C208M	19A116656P200J4	Ceramic disc: 200 pf ±5%, 500 VDCH, temp coef -470 PPM.
C208H	19A116656P180J4	Ceramic disc: 180 pf ±5%, 500 VDCw, temp coef -470 PPM.
Ç209 <b>LL</b>	19A116656P330J15	and and start coo small storm and
		Ceramic disc: 300 pf ±5%, 500 VDCW, temp coef

SYMBOL	GE PART NO.	DESCRIPTION
C209M	19A116656P200J4	Ceramic disc: 200 pf ±5%, 500 VDCb, temp coef -470 PPM.
C209H	19A113356P180J4	Ceramic disc: 180 pf r5%, 500 VDCm, temp coef ~170 PPM.
C2101T	19A700105P44	Mica: 220 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C210L	19A700105P41	Mica: 180 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.
C210M and C210H	19A700105P38	Mica: 150 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C211LL and C211L	19A700105P41	Mica: 180 pf r5%, 500 VDCh; sim to Electro Motive Type DM-15.
C211M	19A700105P36	Mica: 120 pf ±5%, 500 VDCb; sim to Electro Notive Type DM-15.
C211H	19A700105P34	Mica: 100 pf ±5%, 500 YDC%; sim to Electro Motive Type DM-15.
C315FT	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C212L	19A700105P38	Mica: 150 pi £5%, 500 YDCw; sim to Electro Motive Type DM-15.
C212M and C212H	19A700105P36	Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C213LL and C213L	19A116655P19	Ceramic disc; 1000 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.
C213M and C213H	19A116655P17	Ceramic disc: 680 pf £20%, 1000 VDCh; sim to RMC Type JF Discap.
C214 C215	19A116966P107 5496267P11	Metallized polyester: 0.1 µf ±10%, 50 VDCW.  Tantalum: 38 µf ±20%, 15 VDCm; sim to Sprague
C216 and C217	19a116a55P23	Ceramic disc: 3900 pf t20%, 1000 VDCw; sim to RMC Type JF Discap.
C218LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C218L	19A700105P44	Mica: 220 pf ±5%, 500 VDCb; sim to Electro Motive Type DM-15.
C218M and C218H	19A700105P41	Mica: 180 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.
C219LL	7489162P43	Silver mica; 470 pf ±5%, 300 VDCm; sim to Electro Motive Type DM-15.
C219L	7489162P43	Silver mica: 470 pf ±5%, 300 VDC%; sim to Electro Motive Type DM-15.
C219M	7489162P43	Silver mica: 470 pf ±5%, 300 VDCh; sim to Electro Motive Type DM-15.
C219H	7489162P41	Silver mica: 390 pf ±5%, 500 YDCw; sim to Electro Motive Type DM-15.
C22014	7489162P43	Silver mica; 470 pf ±5%, 300 VDC%; sim to Electro Motive Type DM-15.
C220L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C220M	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C220H	7489162P41	Silver mica: 390 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.
C22111	19A116656P160J3	Ceramic disc: 180 of ±5%, 500 VDCW, temp coef -330 PPM.
C221L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCh, temp coef -150 PPM.
C221#	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 YDCm, temp coef -80 PPM.
C221H	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCh, temp coef 0 PPM.
C22211	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCm, temp coef ~330 PPM.
C222L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.
C222M	19A116656P110J8	Ceramic disc; 110 pf ±5%, 500 VDCW, temp coef -80 PPM.
C222H	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef 0 PPM.

SYMBOL	GE PART NO.	DESCRIPTION
C22314	19A700105P41	Mica: 180 pf £5%, 500 VDC%; sim to Electro Motive Type DM-15.
C223L and C223M	19A700105P46	Mica: 270 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C223H	19A700105P41	dica: 180 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.
C2241.L	7489162P41	Silver mica; 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C224L	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C224 M	19A700105P36	Mica: 120 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.
C224H	19A700105P41	Nica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C22514.	19A700105P41	Mica: 180 pf ±5%, 500 VDC%; sim to Electro Motive Type DM-15.
C225L	19A700105P38	Mica: 150 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.
C225M and C225H	19A700105P36	Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C226LL and C226L	19a116655P19	Ceramic disc: 1000 pf £20%, 1000 VDCW; sim to RMC Type Jf Discap.
C226M and C226H	19A116655P17	Ceramic disc: 680 pf $\pm 20\%$ , 1000 VDCh; sim to RMC Type JF Discap.
C227	19A115965P107	Metalized polyester: 0.1 µf ±10%, 50 VDCW.
C228	19A116555P23	Ceramic disc: 3900 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.
C229	5496267P13	Tantalum: 2.2 µf ±20%, 20 VDCh; sim to Sprague Type 150D.
C230LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.
C230L	19A116656P6840	Ceramic disc: 68 pf ±5%, 500 VDCm, temp coef O PPM.
C230M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef 0 PPM.
C230H	19A11G556P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.
C231LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.
C231L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCw, temp coef 0 PPM.
C231M	19All6656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCh, temp coef 0 PPM.
C231H	19A116656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef O PPM.
C232 and C233	19Al16655P23	Ceramic disc: 3900 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.
€2341.L	19A116d56P82J0	Ceramic disc: 82 pf ±5%, 500 VDCw, temp coef 0 PPM.
C234L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCm, temp coef 0 PPM.
C234M	19A116356P53J0	Ceramic disc: 56 pf ±5%, 500 VDCw, temp coef 0 PPM.
C234H	19A116356P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.
C235LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCw, temp coef 0 PPM.
C235L	19A116356P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.
C235M	19All6656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCk, temp coef 0 PPM.
C235H	19A116656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.
C236LL	19Al16656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.
C236L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.
C236M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef 0 PPM.
C236H	19A116656P47J0	Ceramic disc: 47 pi ±5%, 500 VDCh, temp coef

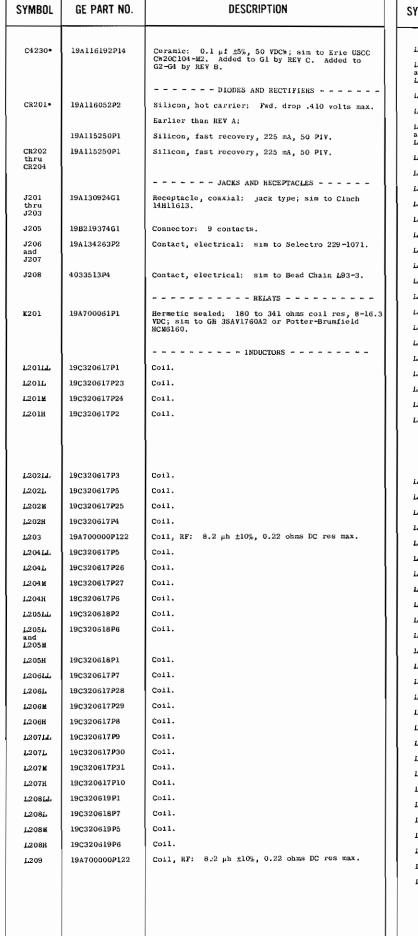
SYMBOL	GE PART NO.	DESCRIPTION
C2371.L	19A116d56P82J0	Ceramic disc: 82 pf ±5%, 500 VDCm, temp coe:
C237L	19A116356P68J0	Ceramic disc: 68 pf ±5%, 500 VDCH, temp coe: 0 PPM.
C237M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCh, temp coel
C237H	19A116J56P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coe.
C238LL	7489162P39	Silver mica; 330 pf ±5%, 500 VDCM; sim to Electro Motive Type DM-15.
C238L	19A700105P44	Mica: 220 pf ±5%, 500 YDCm; sim to Electro Motive Type DM-15.
C238M and C238H	19A700105P41	Mica: 180 pf ±5%, 500 YDCm; sim to Electro Motive Type DM-15.
C239LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCm; sim to Electro Motive Type DM~15.
C239L	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Type DM-15.
C239M and C239H	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Type DM-15.
C240LL	7489162939	Silver mica: 330 pf ±5%, 500 VDCh; sim to blectro Motive Type DM-15.
C240L	19A700105P44	Mica: 220 pf ±5%, 500 VDCh; sim to Electro Notive Type DM-15.
C240M and C240H	19A700105P41	Mica: 180 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.
C24114	7489162P39	Silver mica: 330 pf $\pm$ 5%, 500 VDCW; sim to Electro Motive Type DM-15.
C241L	19A700105P44	Mica: 220 pf $\pm 5\%$ , 500 VDCh; sim to Electro Type DM-15.
C241M and C241H	19A700105P41	Mica: 180 pf ±5%, 500 VDC#; sim to Electro Type DM-15.
C24214, and C242L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.
C242M and C242H	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C243LL	7489162P43	Silver mica: 470 pf $\pm 5\%$ , 300 VDCW; sim to Electro Motive Type DM-15.
C243L	7489162P41	Silver mica; 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C243M and C243H	7489162P39	Silver mica: 330 pf ±5%, 500 VDCH; sim to Electro Motive Type DM-15.
C244LL and C244L	7489162P43	Silver mica; 470 pf ±5%, 300 VDCH; sim to Electro Motive Type DM-15.
C244M and C244H	7489162P41	Silver mica: 390 pf ±5%, 590 VDCW; sim to Electro Motive Type DM-15.
C2451.L	7489162P43	Silver mica: 470 pf ±5%, 300 YDCW; sim to Electro Motive Type DM-15.
C245L	7489162P41	Silver mica; 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C245M and C245H	7489162P39	Silver mica: 330 pf ±5%, 500 VDCM; sim to Electro Motive Type DM-15.
C24 6LL and C24 6L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCh; sim to Electro Motive Type DM-15.
C246M and C246H	7489162P41	Silver mica: 390 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.
C2471.1.	7489162P43	Silver mica; 470 pf ±5%, 300 VDCM; sim to Electro Motive Type DM-15.
C247L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.
C247M and C247H	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C248LL and C248L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCH; sim to Electro Motive Type DM-15.

DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	
	002711	10421025000210	Contract divine 122 at 150 Too way	C248M	7489162P41	Silver mica: 390 pf ±5%, 500 VDCb; sim to				<del> </del>		_
Mica: 180 pf ±5%, 500 VDCh; sim to Electro Notive Type DM-15. Mica: 270 pf ±5%, 500 VDCh; sim to Electro	C237LL	19A116656P82J0 19A116656P68J0	Ceramic disc: 82 pf ±5%, 500 VDCh, temp coef 0 PPM.  Ceramic disc: 68 pf ±5%, 500 VDCh, temp coef	and C248H	(403102141	Electro Motive Type DM-15.	C258LL C258L	7489162P41 19A700105P46	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.  Mica: 270 pf ±5%, 500 VDCh; sim to Electro	C269M and C269H	19A700105P36	Mica: 120 pl Motive Type I
Motive Type DM-15.	C237M	19A116656P56J0	O PPM.  Ceramic disc: 56 pf ±5%, 500 VDCm, temp coef	C249LL	7489162P43	Silver mica: 470 pf ±5%, 300 VDCk; sim to Electro Motive Type DM-15.	and C258M	100100100110	Motive Type DN-15.	C270LL and	19A116355P19	Ceramic disc: sim to RMC T;
Mica: 180 pf <u>1</u> 5%, 500 VDCh; sim to Electro Motive Type DM-15.	C237H	19A116656P47J0	O PPM.  Ceramic disc: 47 pf ±5%, 500 YDCh, temp coef	C249L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C258H and C258LL	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C270L C270M and	19A116655P17	Ceramic disc: sim to RMC T)
Silver mica: 180 pf ±5%, 500 VDCh; sam to Electro Notive Type DM-15.	C238LL	7489162P39	0 PPM. Silver mica; 330 pf ±5%, 500 VDCw; sim to	C249M and C249H	7489162P39	Silver mica: 330 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C259L	19A700105P44	Mica: 220 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C271LL	194116655719	Ceramic disc:
Mica: 220 pf 15%, 500 VDCh; sim to Electro Motive Type DM-15.	C238L	19A700105P44	Electro Motive Type DM-15.  Mica: 220 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C250&L	19A116656P160J3	Ceramic disc: 150 pf ±5%, 500 YDCm, temp coef -330 PPM.	C259M	19A700105P36	Mica: 120 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.	and C271L		sim to RMC Ty
Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15. Mica: 180 pf ±5%, 500 VDCh; sim to Electro	C238M and	19A700105P41	Mica; 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DN-15.	C250L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCm, temp coef -150 PPM.	С259Н	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C271M and C271H	19A116655P17	Ceramic disc; sim to RMC T;
Motive Type DM-15.  Mica: 180 pf ±5%, 500 VDCh; sim to Electro	C238H C239LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to	C250M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C260LL	7489162P41	Silver mica: 390 pl ±5%, 500 VDCh; sim to flectro Motive Type DM-15.	C272LL and	19A116655P19	Ceramic disc: sim to RMC Ty
Motive Type DM-15.  Mica; 150 pf ±5%, 500 VDCh; sim to Electro	C239L	19A700105P44	Electro Motive Type DM-15.  Mica: 220 pf ±5%, 500 YDCW; sim to Electro	С250Н	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	C260L and C260M	19A700105P46	Mica: 270 pf ±5%, 500 YDCh; sim to Electro Motive Type DM-15.	C272L C272M	19A116655P17	Ceramic disc: sim to RMC Ty
Motive Type DM-15. Mica: 120 pf ±5%, 500 VDCh; sim to Electro	C239M	19A700105P41	Type DM-15.  Mica: 180 pf ±5%, 500 VDCb; sim to Electro	C2511.L	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef -330 PPM.	C260H and	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	and C272H C273LL	19A116655P19	Ceramic disc:
Motive Type DM~15.	239H	7490100000	Type DM-15.	C251L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.	C261LL C261L	19A700105P44	Mica: 220 pf ±5%, 500 VDCh; sam to Electro	and C273L	131112000112	Sim to RMC Ty
Ceramic disc: 1000 pf £20%, 1000 VDCW; sim to RMC Type JF Discap.	C240LL C240L	7489162P39 19A700105P44	Silver mica: 330 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.  Mica: 220 pf ±5%, 500 VDCh; sim to Electro	C251M C251H	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCH, temp coef -80 PPM.  Ceramic disc: 91 pf ±5%, 500 VDCH, temp coef	C261M	19A700105P36	Motive Type DM-15.  Mica: 120 pf ±5%, 500 VDCW; sim to Electro	C273M and C273H	19A116655P17	Ceramic disc: sim to RMC Ty
Ceramic disc: 680 pf ±20%, 1000 VDCm; sim to RMC Type JF Discap.	C240M	19A700105P41	Motive Type DM-15.  Mica: 180 pf ±5%, 500 VDCb; sim to Electro	C252LL	19A116656P160J3	O PPM.	C261H	19A700105P41	Motive Type DM-15.  Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C274 thru	19A116966P107	Metallized pc
Metailized polyester: 0.1 μf ±10%, 50 VDCw.	and C240H		Motive Type DM-15.	C252L	19Al16656Pl30Jl	-330 PPM.  Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef	C262LL	7489162P41	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C277 C280LL	19x11G656P82J0	Ceramic disc:
Ceramic disc: 3900 pf ±20%, 1000 VDCb; sim to RMC Type JF Discap.	C241LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C252M	19A116656P110J8	-150 PPM.  Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	C262L and	19A700105P46	Mica: 270 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C280L	19A116656P68J0	O PPM.  Ceramic disc:  O PPM.
Tantalum: 2.2 μf ±20%, 20 VDCh; sim to Sprague Type 150D.	C241L	19A700105P44	Mica: 220 pf ±5%, 500 VDCw; sim to Electro Type DM-15.	C252H	19A116656P91J0	-80 PPM.  Cerawic disc: 91 pf ±5%, 500 VDCW, temp coef	C262M C262H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C280M	19A116656P56J0	Ceramic disc:
Ceramic disc: 82 pf ±5%, 500 YDCW, temp coef O PPM.	C241M and C241H	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Type DM-15.		l.	О 2РМ.	and C263LL		Motive Type DM-15.	С280Н	19x116&56P47J0	Ceramic disc: 0 PPM.
Ceramic disc: 68 pl ±5%, 500 VDCw, temp coef 0 PPM.	C242IL and	7489162P43	Silver mica: 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.	C253LL	19A116356P160J3	Ceramic disc; 160 pf t5%, 500 VDCW, temp coef	C263L	19A700105P44	Mica: 220 pf +5%, 500 YDCh; sim to Electro Motive Type DM-15.	C2811.L	19A116656P82JO	Ceramic disc:
Ceramic disc; 56 pf ±5%, 500 YDCW, temp coef 0 PPM.	C242L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCH; sim to	C253L	19A116656P130J1	Ceramic disc; 130 pf ±5%, 500 VDCH, temp coef -150 PPM.	C263M	19A700105P3G	Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C281L	19All6656P68J0	O PPM. Ceramic disc:
Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.	and C242H		Electro Motive Type DM-15.	C253M	19A116356P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C263H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C281M	19a116656P56J0	O PPM. Ceramic disc: O PPM.
Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.	C2431.1.	7489162P43	Silver mica: 470 pf ±5%, 300 VDCh; sim to Electro Motive Type DM-15.	С253Н	19A116656P9lJ0	Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef 0 PPM.	C2641.L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM~15.	C281H	19A116656P47J0	Ceramic disc;
Ceramic disc: 68 pf ±5%, 500 VDCw, temp coef 0 PPM.	C243L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.  Silver mica: 330 pf ±5%, 500 VDCW; sim to	C2541.L	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCH, temp coef -330 PPM.	C264L and	19A700105P46	Mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C282I.L	19A116656P82J0	Ceramic disc:
Ceramic disc: 56 pf ±5%, 500 VDCh, temp coef 0 PPM.	C243M and C243H	7489162P39	Electro Motive Type DM-15.	C254L	19Al16056P13OJ1	Ceramic disc: 130 pf ±5%, 500 VDCm, temp coef -150 PPM.	C264M C264H	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C282L	19A116656P68J0	Ceramic disc:
Ceramic disc: 47 pf ±5%, 500 VDCw, temp coef 0 PPM.	C244LL and C244L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCH; sim to Electro Motive Type DM-15.	C254M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCb, temp coef -80 PPM.	265LL	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro	C282M	19A116656P56J0	Ceramic disc: 0 PPM.
Ceramic disc: 3900 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.	C244M and	7489162P41	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C254H	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef 0 PPM.	C265L C265M	19A700105P36	Motive Type DM-15.  Mica: 120 pf ±5%, 500 VDCW; sim to Electro	C282H	19A116656P47J0	Ceramic disc; 0 PPM.
Ceramic disc: 82 pf ±5%, 500 VDCm, temp coef 0 PPM.	C244H C245LL	7489162P43	Silver mica: 470 pf ±5%, 300 VDCH; sim to	C255LL	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef -330 PPM.	C265H	19A700105P41	Motive Type DM-15.  Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C283LL	19A116656P82J0	Ceramic disc: 0 PPM.
Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.	C245L	7489162P41	Electro Motive Type DM-15.  Silver mica: 390 pf ±5%, 500 VDCN; sim to Electro Motive Type DM-15.	C255L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.  Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	and C266LL		Motive Type DM-15.	C283L	19A116656P68J0	Ceramic disc: 0 PPM.
Ceramic disc: 56 pf ±5%, 500 VDCm, temp coef O PPM.	C245M and	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C255M	19A116656P110J8	-80 PPM.  Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef	C266L	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. Mica: 120 pf ±5%, 500 VDCW; sim to Electro	C283M	19A116656P56J0	Ceramic disc. O PPM.
Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.	C245H C246LL	7489162P43	Silver mica: 470 pf ±5%, 300 VDCw; sim to	C255H	19A116656P160J3	О РРМ.	C266M and C266H	19A700105P36	Motive Type DM-15.	С283Н	19A116356P47J0	Ceramic disc. 0 PPM.
Ceramic disc: 82 pf ±5%, 500 VDCh, temp coef 0 PPM.	and C246L		Electro Motive Type DM-15.	C256L	19A116656P130J1	-330 PPM.  Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef	C267LL and C267L	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C284LL C284L	19A700015P38 19A700015P36	Metallized to
Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.	C246M and C246H	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C256M	19A116656P110J8		C267M and	19A700105P36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C284M C284H	19A700015P34 19A116679P140J	Metallized to
Ceramic disc: 56 pf ±5%, 500 VDCh, temp coef 0 PPM.	C2471	7489162P43	Silver mica; 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.	C256H	19A116656P91J0	-80 PPM. Cornmic disc: 91 pf ±5%, 500 VDCW, temp coef	C267H C268LL	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C28514	19A700015P38	Metallized to
Ceramic disc: 47 pf ±5%, 500 VDCH, temp coef 0 PPM.  Ceramic disc: 82 pf ±5%, 500 VDCH, temp coef	C247L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.	C257LL	19A116356P160J3	O PPM.  Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef -330 PPM.	and C268L	104700105925	Motive Type DM-15.  Mica: 120 pf ±5%, 500 VDCW; sim to Electro	C285L C285M	19A700015P36 19A700015P34	Metallized to
Ceramic disc; 68 pf ±5%, 500 VDCW, temp coef	C247M and C247H	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C257L	19A116656P13OJ1	Ceramic disc: 130 pf ±5%, 500 VDCh, temp coef -150 PPM.	C268M and C268H	19A700105P36	Motive Type DM~15.	C285H	19A116679P140J	Mica: 140 p
O PPM.  Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef	C248LL and	7489162P43	Silver mica: 470 pf ±5%, 300 VDCH; sim to Electro Motive Type DM-15.	C257M	19Al16656Pl10J8		C269LL and C269L	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C286 thru C293	19A11665\$P23	Ceramic disc RMC Type JF
O PPM.  Ceramic disc: 47 pf ±5%, 500 VDCw, temp coef	C248L			C257H	19Al16656P9lJ0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	(2.00H			C294LL C294L	19A700015P34 19A700015P32	Teflon/Mica: Teflon/Mica:
O PPM.										523.1		

E PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
162 <b>P</b> 41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C2581.1.	7489162P41	Silver mica: 390 pf ±5%, 500 VDC%; sim to Electro Motive Type DM-15.	C269M and	19A700105236	Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C294M C294H	19A700015P30 19A700015P28	Metallized teflon: 110 pf ±5%, 250 VDCh.
162P43	Silver mica: 470 pf ±5%, 300 VDCh; sim to Electro Motive Type DM-15.	C258L and C258M	19A700105P46	Mica: 270 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C269H C270LL and	19A116355P19	Ceramic disc: 1000 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.	C4201LL*	19A116d56P91J2	Metallized teflon: 91 pf ±5%, 250 VDCw.  Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef ~220 PPM.
62P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C258H and C258LL	19A700105P41	Mica: 180 pf £5%, 500 VDCh; sim to Electro Motive Type DM-15.	C270L C270M	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCM;		19A116656P82J1	In REV A α earlier: Ceramic disc: 82 pf ±5%, 500 VDCh, temp coef
62P39	Silver mica: 330 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C259L	19A700105P44	Mica: 220 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	270H C271LL	194116655719	sim to RMC Type JF Discap.  Coramic disc: 1000 pf ±20%, 1000 VDCW;	C4201L	19A116656P68J1	-150 PPM.  Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef
6656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef -330 PPM.	C259M	19A700105P36	Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	and C271L		sim to RMC Type JF Discap.	C4201M	19A116656P56J1	-150 PPM.  Ceramic disc: 56 pf ±5%, 500 VDCH, temp coef -150 PPM.
6656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCH, temp coef -150 PPM.	С259Н	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C271M and C27tH	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDC%; sim to RMC Type JF Discap.	C4201H	19A116656P51J1	Ceramic disc: 51 pf ±5%, 500 VDCW, temp coef -150 PPM.
16656P110J8 16656P91J0	Ceramic disc: 110 pf ±5%, 500 VDCh, temp coef -80 PPM.  Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef	C260LL	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C272LL and C272L	19A116655P19	Ceramic disc: 1000 pf $\pm 20\%$ , 1000 VDCW; sim to RMC Type JF Discap.	C4202£L	19A700015P30	Metallized teflon: 110 pf ±5%, 250 VDCW.
16656P160J3	O PPM.  Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef	C260L and C260M	19A700105P46	Maca: 270 pf ±5%, 500 VDCh; sim to Electro Motave Type DM-15.	C272M and	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCm; Sim to RMC Type JF Discap.	C4202L C4202M	19A700015P28 19A700015P25	Metallized teflon: 91 pf z5%, 250 VDCW.  Metallized teflon: 68 pf z5%, 250 VDCW.
16656P130J1	-330 PPM.  Ceramic disc: 130 pf ±5%, 500 VDCw, temp coef	C260H and C2611L	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C272H C273LL and	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDC%; sim to RMC Type JF Discap.	C4202H C4203LL	19A700015P23 19A116656P15J1	Metallized teflon: 56 pf ±5%, 250 VDCW.  Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef
16656P110J8	-150 PPM.  Ceramic disc: 110 pf ±5%, 500 VDCw, temp coef -80 PPM.	C261L	19A700105P44	Mica: 220 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C273L C273M	19A116655P17	Ceramic disc: 580 pf ±20%, 1000 VDCh;	C4203L	19A116656P13J1	-150 PPM.  Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef
l16656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	C261M	19A700105P36	Mica: 120 pf ±5%, 500 YDCh; sim to Electro Motive Type DM~15.	and C273H C274	19A116966P107	sim to RMC Type JF Discap.	C4203M	19A116656P12J1	-150 PPM.  Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef -150 PPM
l16656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCh, temp coef -330 PPM.	C261H	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	thru C277	1	Metallized polyester: 0.1 μf ±10%, 50 VDCh.	C4203H	19A116656P10J1	Ceramic disc: 10 pf ±5%, 500 VDCH, temp coef -150 PPM.
16656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCm, temp coef -150 PPM.	C262LL C262L	7489162P41 19A700105P46	Silver maca: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.  Mica: 270 pf ±5%, 500 VDCh; sim to Electro	C2801.1.	19A116356P82JO	Ceramic disc: 82 pf ±5%, 500 VDCm, temp coef O PPM.	C4204LL	19A116679P140J	Mica: 140 pf ±5%, 250 VDCW.
16656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	and C262M		Motive Type DM-15.	C280L	19A116656P68J0 19A116656P56J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM. Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef	C4204L C4204M	19A700015P30 19A700015P28	Metallized teflon: 110 pf ±5%, 250 VDCW.  Metallized teflon: 91 pf ±5%, 250 VDCW.
16656P91J0	Ceramic disc: 91 pf ±5%, 500 YDCW, temp coef 0 PPM.	C262H and C263LL	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C280H	19A116356P47J0	O PPM.  Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef	C4204H	19A700015P27	Metallized teflon: 82 pf ±5%, 250 VDCh.
							о ррм.			
.6856P160J3	Ceramic disc: 160 pf ±5%, 500 VDCM, temp coef -330 PPM.	C263L	19A700105P44	Mica: 220 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C28114	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCh, temp coef	C4205LL*	19A700015P3l	Metallized teflon: 120 pf ±5%, 250 VDCW.
6656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCh, temp coef -150 PPM.	C263M	19A700105P36	Mica: 120 pf ±5%, 500 VDCk; sim to Electro Motive Type DM-15.	C281L	19A116656P68J0	O PPM.  Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef O PPM.		19Al16656P82Jl	In REV A & earlier: Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef
6656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCH, temp coef -80 PPM.	C263H	19A700105P41	Mica: 180 pf ±5%, 500 VDCb; sim to Electro Motive Type DM-15.	C281M	19x116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCm, temp coef 0 PPM.	C4205L*	19A700015P28	-150 PPM.  Metallized teflon: 91 pf ±5%, 250 VDCW.
16656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCm, temp coef 0 PPM.	C264LL	7489162P41	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С281Н	19All6656P47J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.		10411627001001	In REV B & earlier: Mica: 100 pf ±5%, 250 VDCW.
116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDC%, temp coef -330 PPM.	C264L and C264M	19A700105P46	Mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C282LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4205M	19A116679P100J 19A700015P27	Metallized teflon: 82 pf ±5%, 250 VDCw.
.16656P130J1 .16656P110J8	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.  Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	C264H and	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C282L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4205H C4206LL*	19A700015P26 19A116656P91J2	Mctallized teflon: 75 pf ±5%, 250 VDCW.  Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef
116656P91J0	-80 PPM.  Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef	C265LL C265L	19A700105P4-1	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM~15.	C282M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef 0 PPM.			-220 PPM. In REV A & earlier:
l16656P160J3	O PPM.  Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef	C265 <b>M</b>	19A700105P36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C282H	19A116656P47J0 19A116656P82J0	Ceramic disc: 47 pf ±5%, 500 VDCh, temp coef 0 PPM. Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef		19A116656P82J1	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef -150 PPM.
l16656P130J1	-330 PPM.  Ceramic disc: 130 pf ±5%, 500 VDCh, temp coef -150 PPM.	C265H and	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C283L	19A116656P68J0	O PPM.  Ceramic disc: 68 pf ±5%, 500 VDCu, temp coef	C4206L	19A116656P68J1	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM.
116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C266LL C266L	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C283M	19A116656P56J0	O PPM.  Ceramic disc: 56 pf ±5%, 500 VDCk, temp coef O PPM.	C4206M C4206H	19A116656P56J1 19A116656P51J1	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -150 PPM.  Ceramic disc: 51 pf ±5%, 500 VDCW, temp coef
116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCh, temp coef 0 PPM.	C266M and	19A700105P36	Mica; 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С283Н	19A116356P47J0	Ceramic disc: 47 pf ±5%, 500 VDCw, temp coef 0 PPM.	C4210	19A116655P19	-150 PPM.  Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to
16656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCm, temp coef -330 PPM.	C266H C267LL and	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C284LL	19A700015P38	Metallized teflon: 240 pf ±5%, 250 VDCW.	thru C4216	10.110455000	RMC Type JF Discap.  Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim to
16656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCN, temp coef -150 PPM.	C267L	19A700105P36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro	C284L C284M	19A700015P36 19A700015P34	Metallized teflon: 200 pf ±5%, 250 VDCW.  Metallized teflon: 160 pf ±5%, 250 VDCW.	C4220	19A116655P23	RMC Type JF Discap.  Ceramic disc: 680 pf ±20%, 1000 VDCW; sim to
16656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef	and C267H		Motive Type DM-15.	C284H C285LL	19All6679P140J 19A700015P38	Mica: 140 pf ±5%, 250 VDCm.  Metallized teflon: 240 pf ±5%, 250 VDCm.	and C4222		RMC Type JF Discap.
116656P160J3	O PPM. Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef	C268LL and C268L	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C285L	19A700015P36	Metallized teflon: 200 pf ±5%, 250 VDCW.	C4223 thru C4225	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
l16656Pl30J1	-330 PPM.  Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef	C268M and C268H	19A700105P36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C285M C285H	19A700015P34 19A116679P140J	Metallized teflon: 160 pf ±5%, 250 VDCW.  Mica: 140 pf ±5%, 250 VDCW.	C4226 thru C4228	19A116655P23	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
l16656P110J8	~150 PPM.  Ceramic disc: 110 pf ±5%, 500 VDCk, temp coef ~80 PPM.	C269LL and C269L	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C286 thru C293	19A116655P23	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C4229	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDC%, temp coef 0 PPM.	C209L			C29414L	19A700015P34	Teflon/Mica: 160 pf ±5%, 250 VDCw. Teflon/Mica: 130 pf ±5%, 250 VDCw.			
					C294L	19A700015P32	TOTAL MARCH. AND PAR LONG MAN TANGET			(Cont'd on Page 17)

E PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBO	GE PART NO.	DESCRIPTION
114100014		L2 10LL	19C320617P11	Coil.	1,225	19A700000P122	Coat BP: 9 9 100 0 99 ph pp DG page
116192P14	Ceramic: 0.1 µf ±5%, 50 VDC%; sim to Erie USCC CM2OC104-M2. Added to G1 by REV C. Added to G2-G4 by REV B.	L210L	19C320617P4	Coil.	thru L228	1541000007122	Coii, RF: 8.2 μh ±10%, 0.22 ohms DC res
	Garage by Ray B.	and L210M			L229	L 19C320617P16	Coil.
		£210H	19C320617P12	Coil.	L229		Coil.
116052P2	Silicon, hot carrier: Fwd, drop .410 volts max.	£211££	19C32O618P2	Coil.	1,229	190320617912	Coil.
	Earlier than REV A:	L211L	19C320618P6	Coil.	L2291	19C320617P17	Coil.
115250Pl	Silicon, fast recovery, 225 mA, 50 PIV.	and L211M			L230	L 19C320617P16	Coil.
115250P1	Silicon, fast recovery, 225 mA, 50 PIV.	L211H	19C32O618P1	Coil.	L2301	19C320617P35	Coil.
	TAGIN AND DESCRIPTION	L214LL	19C32O617P13	Coil.	L230	19C320617P12	Coil.
130924G1	Receptacle, coaxial; jack type; sim to Cinch	12141	19C320617P32	Coil.	L230	19C320617P17	Co11.
13052401	14H11613.	1.214 M	19C320617P18	Coil.	L2311	L 19C320617P16	Co11.
219374G1	Connector: 9 contacts.	L214H	19C320617P14	Coil.	L2311	19C320617P35	Coil.
134263P2	Contact, electrical: sim to Selectro 229-1071.	L215LL	19C320617P13	Coil.	L231	l	Coil.
		12151	19C320617P33	Coll.	L231	19C320617P17	Coil.
3513 <i>P</i> 4	Contact, electrical: sim to Bead Chain L93-3.	L215M	19C320617P34	Coil.	L2321	1	Coil,
	0.00	L215H	19C320617P18 19C320617P13	Coil.	L2321	<b>I</b>	Coil.
700001 P1	Variable cooled. 180 to 24) object cot large 8-16 2	L216L	19C320617P13	Coil.	L2321	19C320617P12 19C320617P17	Coil.
700061P1	Hermetic sealed: 180 to 341 ohms coil res, 8-16.3 VDC; sim to GE 3SAV1750A2 or Potter-Brumfield	L216M	19C320617P34	Coil.	L2321		Coil.
	HCM6160.	L216H	19C320617P18	Coil.	L2331		Coil.
		L217LL	19C320617P15	Coil.	and 1,2334		6011.
320617P1	Coil.	L217L	19C320617P5	Coil.	L233E	19C320618P1	Coil.
320617P23	Coil,	L217M	19C320617P26	Coil.	L2341		Coil.
320617P24	Coil.	L217H	19C320617P6	Coil.	L2341	1	Coil,
320617P2	Coil.	L218LL	19C320617P15	Coll.	and L234h		
320617P3	Coil.	1218L	19C320617P5	Coil.	1.2341	19C320618P1	Coil.
320617₽5	Coil.	L218M	19C320617P26	Coil,	1.2351	L 19C320618P2	Coil.
320617 <b>P</b> 25	Coil.	L218H	19C32Od17P6	Coil.	1,2351	19C320618P6	Coil.
320617P4	Coil.	L219LL	19C32O617P15	Coil.	2351		
700000P122 320617P5	Coil, RF: 8.2 µh ±10%, 0.22 ohms DC res max.	L219L	19C32O617P5	Coil.	1,2351	19C320618P1	Coil.
320617P3 320617P26	Coil.	L219M	19C320617P26	Coil.	1,2361	L 19C320618P2	Coil.
320617P27	Coil.	L219H	19C320617P6	Coil.	L2361	19C32O618P6	Coil.
320617P6	Coil.	L220LL	19C320617P15	Coil.	1,2361		
320618P2	Coil.	L220L	19C320617P5 19C320617P26	Coil.	1,2361		Coil.
320618P6	Coil.	L220M L220H	19C320617P26	Coil.	12371		Coil.
		L221LL	19032061991	Coil.	L2371		Coil.
320618P1	Coil.	L221L	19C320618P7	Coil.	L2371		Coil.
320617P7	Coil.	L221M	19C320619P5	Coil.	1,2381		Coil.
320617P28	Coil.	L221H	19C320619P6	Coil.	L238		Coil.
320617P29	Coil.	L222LL	19C320619P1	Coil.	L238		Coil.
320617P8	Coil.	L222L	19C320618P7	Coil.	1.238		Coil.
320617P9	Coil.	L222M	19C320619P5	Coil.	L239		Coil.
320617 <b>P</b> 30	Coil.	L222H	19C320619P6	Coil.	1.239	19C320617P38	Coil.
320617P31	Coil.	L223LL	19C320619P1	Coil.	1.239	19C320617P39	Coil.
320617P10	Coil.	L222L	19C320618P7	Coil.	L2391	19C320617P40	Co11.
320619P1 320618P7	Coil.	L222M	19C320619P5	Coil.	1,240	L 19C320617P37	Coil.
320618P7 320619P5	Coil.	L223H	19C320619P6	Coil.	L240.	. 19C320617P38	Coil.
320619P5 320619P6	Coil.	L224 LL	19C320619P1	Coil.	L240		Coil.
700000P122	Coil, RF: 8.2 µh ±10%, 0.22 ohms DC res max.	L224L	19C320618P7	Coil,	L240		Coil.
		1.2 24 ₪	19C320619P5	Coil.	1.241		Coil,
		L224H	19C320619P6	Coil.	1.241		Coil.
					L241	19C320617P43	Coil.
					L241		Coil.

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
1005	1017000000100		L242LL	19C320617P41	Coil.
L225 thru	19A700000P122	Coll, RF: 8.2 μh ±10%, 0.22 ohms DC res max.	L242L	19C320617P42	Coil.
L228 L229LL	19C320617P16	Coil.	L242M	19C320617P43	Coil.
L229L	19C320617P35	Coil.	L242H	19C320617P44	Co11.
L229M	190320617P12	Coil.	1.2431.1.	19C320617P41	Coil.
L229H	19C320617P17	Coil.	L243L	19C320617P42	Coil.
L230LL	19C320617P16	Coil.	1.243M	19C320617P43	Coil.
L230L	19C320617P35	Coil.	1.243H	19C320617P44	Coil.
L230M	19C320617P12	Coil.	1,2441.1,	19C32O617P41	Coil.
L230H	19C320617P17	Coll.	L244L	19C320617P42	Coil.
L231LL	19C320617P16	Co11.	L244 N	19C320617P43	Coil.
L231L	19C320617P35	Co11.	1.244H	19C320617P44	Coil.
L231M	190320617912	Coil.	L2451L	19A129360P9	Coil.
L231H	19C320617P17	Coil.	£245L	19A129360P6	Coil.
L23214	190320617916	Coil.	L245M	19A129360P4	Coil.
L232L	19C320617P35	Coil.	L245H	19A129360P1	Coil.
L232N	19C320617P12	Coil.	L246LL	19A129360P10	Coil.
L232H	19C32O617P17	Coil.	L246L	19A129360P7	Coil.
L233LL	19C32O618P2	Coil.	L24 GM	19A129360P3	Coil.
L233L	19C320618P6	Coil.	L246H	19A129360P2	Coil.
and 1.233%			1.2471.1.	19A129360P11	Coil.
L233H	19C320618P1	Coil.	L247L	19A129360P8	Coil.
L234LL	19C320618P2	Coil.	L247M	19A129360P5	Coil.
L234L	19C320618P6	Coil,	1.247н	19A129360P3	Coil.
and L234M			L248LL	19A129360P9	Coil.
1.234H	19C320618P1	Coil.	L248L	19A129360P6	Coil.
L235LL	19C320618P2	Coil.	L248M	19A129360P4	Coil.
L235L	19C320618P6	Coil.	L248H	19A129360P1	Coil.
and L235M			1.2491.1.	19C320617P41	Coil.
L235H	19C320618P1	Coil.	L249L	19C320617P42	Coil.
لىل236نىل	19C32O618P2	Coil.	L249 M	19C320617P43	Coil.
L236L	19C32O618₽6	Coil.	L249H	19C32O617P44	Coil.
and L236 <u>M</u>			L250LL	19C320617P41	Co11.
L236H	19C320618P1	Coil.	L250L	19C320617P42	Coil.
L237LL	19C320617P37	Coil.	L250N	19C320617P43	Coil.
L237L	19C320617P38	Coil.	1.250H	19C320617P44	Coil.
L237M	19C32O617P39	Coil.	L251 thru	19A700000P16	Coil, RF: 2.7 µh ±10%, 1.20 ohms DC res max.
L237H	19C320617P40	Coil.	1,254		
123814	19C320617P37	Coil.	1.255	19A700000P19	Coil, RF: 4.7 µh ±10%, 0.210 ohms DC res max.
L238L	19C320617P38	Coil.	L256 and	19A700000P16	Coil, RF: 2.7 µh ±10%, 1.20 ohms DC res max,
L238M	19C320617P39	Coil.	L257	101500000000	0-11 ng, 2 2 th 100 0 140 shap 00 mos
L238H	19C320617P40	Coil.	1,258	19A700000P17	Coil, RF: 3.3 µh ±10%, 0.140 ohms DC res max.
L239LL	19C320617P37	Coil,	L259 thru	19A129346G1	Coil.
L239L	19C320617P38	Coil.	L263		
L239M	19C320617P39	Coil.	0011	10411501001	Silicon, NPN; sim to Type 2N3904.
L239H	19C320617P40	Coil,	Q211	19A115910P1 19A115768P1	Silicon, PNP; sim to Type 2N3702.
1.2401.1	19C320617P37	Coil.	Q212 thru	INTIGORI	Danielli, and the Appendix
L240L	19C320617P38	Coil.	Q214	19A115910P1	Silicon, NPN; sim to Type 2N3904.
L240M	19C320617P39	Coil.	Q215 Q216	19A115779P1	Silicon, PNP; sim to Type 2N3251.
L24 0H	19C320617P40	Coil.	42.15		
J.24 LLL	19C320617M1	Coil.			
L241L	19C320617P42	Coil.			
L241M	19C320617P43	Coil.			
L24 1H	19C320617P44				



SYMBOL	GE PART NO.	DESCRIPTION		SYMBOL	GE PART NO.	
L210LL	19C320617P11	Coil,		L225	19A700000P122	Coil, R
L210L and	19C320617P4	Coil,		thru L228		
L210M				L229LL	19C320617P16	Coll.
L210H	19C320617P12	Coil.	- [	L229L	19C320617P35	Coil.
L211LL	19C320618P2	Coil.		1229М	19C32O617P12	Co11,
L211L and L211M	19C320618P6	Coil.		L229H	190320617917	Coil.
L211H	19C320618P1	Coil,		L230LL L230L	19C320617P16 19C320617P35	Coil.
L214LL	19C320617P13	Coil.	- [	L230M	19C320617P12	Coil.
L214L	19C320617P32	Coil.		1230н	19C320617P17	Coil.
L214M	19C320617P18	Coil.		L2311.L	19C32O617P16	Coil.
1.214H	19C32O617P14	Coil.		L231L	19C320617P35	Coil,
L215LL	19C320617P13	Coil.	ı	L231M	19C320617P12	Coil,
L215L	19C320617P33	Coil.		L231H	19C320617P17	Coil.
L215M	19C320617P34	Coil.	١	L232LL	19C32O617P16	Coil.
L215H	19C320617P18	Coil,	١	L232L	19C320617P35	Coil.
L216LL	19C320617P13	Coil,	١	123211	19C320617P12	Coil.
L216L	190320617833	Coil.	١	L232H	19C320617P17	Coil.
L216M	19C320617P34	Coil.	ļ	L233LL	19C320618P2	Coil.
L216H L217LL	19C320617P18 19C320617P15	Coil.	l	L233L and	19C320618P6	Coil.
L217L	19C320617P5	Coll.		1.233M 1.233H	19032061821	Coil.
L217M	19C320617P26	Coil.		L234LL	19C320618P2	Coil.
L217H	19C320617P6	Coil.	١	L234L	19C320618P6	Coil.
L218LL	19C320617P15	Coil.	ļ	and L234M		
L218L	19032061725	Coil.		L234H	19C320618P1	Coil.
L218M	19C320617P26	Coil,		L235LL	19C32O618P2	Coil.
L218H	190320617P6	Coil.		L235L	19C320618P6	Coil,
1,2191.L	19C320617P15	Coil.		and L235M		
L219L	19C320617P5	Coil.		1235H	19C320618P1	Coil.
L219M	19C320617P26	Coil,		L236LL	19C320618P2	Coil,
L219H	19C320617P6	Coil.		L236L and	19C320618P6	Coil,
L220LL L220L	19C320617P15	Coil.		L236M	10022001891	Coil.
L220M	19C320617P26	Coil,		L236H L237LL	19C320618P1 19C320617P37	Coil.
L220H	190320617P6	Coil.		L237L	19C320617P38	Coil.
1.2211.1.	19C32O619P1	Coil.		L237M	19C320617P39	Coil.
L221L	19C32O618P7	Coil.	П	L237H	19C320617P40	Coil.
1.2211	19C320619P5	Coil,	П	L23814.	19C320617P37	Coil.
L221H	19C32O619P6	Coil.	lì	L238L	19C320617P38	Coil.
L222LL	19C32O619PL	Coil.		L238M	19C320617P39	Coil.
L222L	19C32O618P7	Coil.		L238H	19C320617P40	Coil.
L222M	19C32O619P5	Coil.		1.2391.L	19C320617P37	Coil.
L222H	19C320619P6	Coil.		L239L	19C320617P38	Coil.
L223LL	19C320619Pl	Coil.		L239M	19C320617P39	Coil.
L222L	19C320618P7 19C320619P5	Coil.		L239H	19C320617P40	Coil.
1.222M 1.223H	19C320619P6	Coil.		1.24 OLL	19C320617P37 19C320617P38	Coil.
1,2241,1.	19C320619P1	Coll.		L240L L240M	19C320617P39	Coil.
12246	19C320618P7	Coil.		1240H	19C320617P40	Coil.
L224M	19C32O619P5	Coil.		1.24 1.LL	19C320617P41	Coil.
L224H	19C32O619P6	Coil.		L241L	19C320617P42	Coil.
				L241M	19C320617P43	Coil.
				L24 1H	19C320617P44	Coil.
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DF-3155

#### LBI4898

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SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
			R222L	19A700113P5	Composition; 3.9 ohms ±5%, 1/2 w.	R235 M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.
R201	19A700106P77	Composition: 3.9K ohms ±5%, 1/4 w.	R222M	7147161P27	Composition: 2.0 ohms 45%, 1/2 w.	R235H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.
R202	3R152P511J	Composition: 510 ohms £5%, 1/4 w.	R222H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R236	19A700113P29	Composition: 39 ohms ±5%, 1/2 w.
R203LL	19A700113P17	Composition: 12 ohms ±5%, 1/2 w.	R223LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	thru R243		
R203L	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.	R223L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R244 thru	19A700111P39	Composition: 100 ohms £5%, 2 w,
R203M	19A700113P13	Composition: 8.2 ohms ±5%, 1/2 w.	R223M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 %.	R246		
R203H	19A700113P7	Composition: 4.7 ohms ±5%, 1/2 w.	R223H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R249	19C320212P2	Shunt resistor.
R204LL	19A700113P17	Composition: 12 ohms ±5%, 1/2 w.	8224 LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R250 and	19C320212P1	Shunt resistor.
R204L	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.	R224L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	8251		
R204M	19A700113P13	Composition: 8.2 ohms ±5%, 1/2 w.	R224M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R252	19A700106P91	Composition: 15K ohms ±5%, 1/4 w.
R204H	19A700113P7	Composition: 4.7 ohms ±5%, 1/2 w.	R224H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R253	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.
R205 and	19A700113P29	Composition: 39 ohms ±5%, 1/2 w.	R225LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R254	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.
R206	101700110850	0.07	R225L	19A700113P5	Composition: 3.9 ohms £5%, 1/2 w.	R255	19A116278P253	Metal film: 3480 ohms ±, 1/2 w.
R207LL	19A700113P59 19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R225M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R256	19A116278P201	Metal film: 1K ohms ±2%, 1/2 w.
R207L R207M	194700113P59	Composition: 680 ohms ±5%, 1/2 w.	к225н	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R257	19A116278P261	Metal film: 4220 ohms ±2%, 1/2 w.
R207H	3R78P911J	Composition: 680 ohms ±5/c, 1/2 w.	R226LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R258	19A116278P269	Metal film: 5110 ohms ±2%, 1/2 w.
R207H R208LL	194700112959	Composition: 910 ohms ±5%, 1 w.  Composition: 680 ohms ±5%, 1 w.	R2264.	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R259	19A116278P261	Metal film: 4.22K ohms ±2%, 1/2 W.
R208L	19A700112P59	Composition: 680 ohms ±5%, 1 w.	R226M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R261	19A116559P102	Variable, cermet: 5K ohms ±20%, .5 w; sim to CTS Series 360.
R208M	19A700112P59	Composition: 680 ohms ±5%, 1 w.	R226H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R262	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.
R208H	3R78P911J	Composition: 910 ohms ±5%, 1 w.	R227LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R263	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.
R209LL	19A700112P13	Composition: 8.2 ohms ±5%, 1 w.	R227L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R264	19A700113P41	Composition: 120 ohms ±5%, 1/2 w.
R209L	19A700112P13	Composition: 8.2 ohms ±5%, 1 w.	R227M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R235	19A700113P55	Composition: 470 ohms ±5%, 1/2 w.
R209M	19A700112P13	Composition: 8.2 ohms ±5%, 1 w.	R227H	7147161P22 19A700113P11	Composition: 1.2 ohms ±5½, 1/2 w.  Composition: 6.8 ohms ±5½, 1/2 w.	R266	19A700106P63	Composition: 1K ohms ±5%, 1/4 w.
R209H	19A700112P9	Composition: 5.6 ohms ±5%, 1 w.	R228LL R228L	19A700113P11	Composition: 3.9 ohms ±5%, 1/2 w.	R267	19A700106P69	Composition: 1.8K ohms ±5%, 1/4 w.
						R268	19A700106P15	Composition: 10 ohms ±5%, 1/4 w.
K2101T	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R228M	7147161927	Composition: 2.0 ohms g5%, 1/2 w.	R269	194700113P15	Composition: 10 ohms ±5%, 1/2 *.
R210L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R228H	7147161P22	Composition: 1.2 ohms £5%, 1/2 w.	R270	3R152P241J	Composition: 240 ohms ±5%, 1/4 w.
R210M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R229LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R271	19A700106P75	Composition: 3.3K ohms ±5%, 1/4 w.
R210H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R229L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R272	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.
R211LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R229M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R273	3R78P100K	Composition: 10 ohms ±10%, 1 w.
R211L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R229H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	thru R277		
R211M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R230LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.			VOLTAGE REGULATORS
R211H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R230L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	VR201	4036887P1	Zener: 500 mm, 2.3 v. nominal.
R21214	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R230M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	VR202	4036887P5	Zener: 500 mk, 5.4 v. nominal.
R212L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R230H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.			CABLES
R212M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R231LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	h201	19A129571P1	Strap.
R2 12H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R231L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	#201 #202	198219998P2	Jumper.
R213LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R231M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	w202	198219998P1	Jumper.
R213L	19A700113P5	Composition; 3.9 ohms ±5%, 1/2 w.	R231H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	#203 #204	19C320624P1	Strip, connector.
R213M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R232LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	#205		(Part of printed waring board 19D417923P1).
R213H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R232L	19A700113P5	Composition: 3.9 ohms £5%, 1/2 w.	thru #209		
R214 and	19A700113P29	Composition: 39 ohms ±5%, 1/2 w.	R232M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.			
R215			R232H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.			HEAT SINK ASSEMBLY
R216 thru R218	19A700112P39	Composition: 100 ohms ±5%, 1 w.	R233LL R233L	19A700113P11 19A700113P5	Composition: 6.8 ohms ±5%, 1/2 w.  Composition: 3.9 ohms ±5%, 1/2 w.			19B219688G6 M MADEL AND INTERMITTANT DUTY STATION 19B219688G18 E MADEL
R220LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R233M	7147161927	Composition: 2.0 ohms £5%, 1/2 w.			
R220L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R233H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	C297 and	19A116708P1	Ceramic, feed-thru: 0.01 µf +100% -0%, 500 VDCW; sim to Erie Style 327.
R220M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R2341.L	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	C298		
R220H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R234L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	C299	19A115680P10	Electrolytic: 200 µf +150% -10%, 18 VDC%; sim to Mallory Type TTX.
R221LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R234M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.			
R221L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R234H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.			DIODES AND RECTIFIERS
R221M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R235LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	CR295	19A116783P1	Silicon.
R221H R222LL	Composition: 1. 19A700113P11	2 ohms ±5%, 1/2 w.  Composition: 6.8 ohms ±5%, 1/2 w.	R235L	19A700113P5	Composition: 3.9 ohms £5%, 1/2 w.			

SYMBOL	GE PART NO.	DESCRIPTION			
	_	MISCELLANEOUS			
	19A129361P1	Shield. (Located between L245 & L247, 1			
ļ	19A129331P2	Shield, (Located between L245 & L246).			
	19D416275P2	Filter casting.			
	19A134016P1	Insulator, bushing. (Used with Q217).			
	19Al16023P1	Insulator, plate. (Used with Q217).			
	19D416712P6	Insulator, (Located under Power Amplifa			
	19A129661P1	Insulator. (Located at L298).			
	19B201074P312	Tap screw, Phillips POZIDRIV®: No. 6-32 (Secures Filter Casting).			
	5492178P2	washer, spring tension: sim to wallace 375-20. (Used with Q204-Q209).			
	N207P15C6	Hexnut: No. 8-32. (Used with Q204).			
	19A129434P1	Washer. (Used with C297, C298).			
	N207P16C6	Nut, hex: No. 10-32. (Used with Q205-C			

#### **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a Letter," which is stamped after the model number of the unit. The revision stamped on the unit previous revisions. Refer to the Parts List for descriptions of parts affected by these revis

REV, A ~ Power Amplifier Board 19D417927G1-4

To improve operation. Changed CR201.

REV. B - Power Amplifier Board 19D417927G1

To improve stopband attenuation (25-30 MHz range) Changed C4201LL and C4206LL,

REV. B - Power Amplifier Board 19D417927G2-4

REV. C - Power Amplifier Board 19D417927G1

To improve operation of power control circuit. Added C42:

REV. C - Power Amplifier Board 19D417927G2

To improve low pass filter response. Changed C4205L.

			_			
TION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
PORS	R222L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 %.	R235M	7147161927	Composition: 2.0 ohms ±5%, 1/2 w.
5%, 1/4 w.	R222M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	к235н	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.
6, 1/4 w.	R222H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R236	19A700113P29	Composition: 39 ohms ±5%, 1/2 w.
1/2 *.	R223LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	thru R243		
, 1/2 w.	R223L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R244	194700111P39	Composition: 100 ohms ±5%, 2 %.
i, 1/2 w.	R223M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 %.	thru R246	400.00044.00	
2, 1/2 w.	R223H	7147161P22	Composition: 1.2 ohms 15%, 1/2 w.	R249	19C320212P2	Shunt resistor.
, 1/2 w.	R224LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R250	19C320212PI	Shunt resistor.
1/2 w.	R224L	194700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	and R251	1	
2, 1/2 w.	R224M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R252	19A700106P91	Composition: 15K ohms ±5%, 1/4 %.
, 1/2 w.	R224H	7147161P22	Composition: 1.2 ohms 15%, 1/2 w.	R253	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.
1/2 w.	R225LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R254	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.
	R225L	19A700113P1	Composition: 3.9 ohms ±5%, 1/2 w.	R255	19A116278P253	Metal film: 3480 ohms fa, 1/2 w.
, 1/2 w.	R225M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R256	19A116278P201	Metal film: 1K ohms ±2%, 1/2 w.
, 1/2 w.		7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R257	19A116278P261	Metal film: 4220 ohms ±2%, 1/2 w.
, 1/2 w.	R225H	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R257	19A116278P269	Metal film: 5110 ohms ±2%, 1/2 w.
, 1 w.	R226LL	19A700113P11 19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R259	19A116278P261	Metal film: 4.22K ohms ±2%, 1/2 w.
,, 1 w.	R226L		· ·	11	19A116278P261 19A116559P102	Variable, cermet: 5K ohms ±20%, .5 w; sim to
,, 1 w.	R226M	7147161P27 7147161P22	Composition: 2.0 ohms ±5%, 1/2 w.  Composition: 1.2 ohms ±5%, 1/2 w.	R261	232710332KI02	CTS Series 360.
,, 1 w.	R226H			R262	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.
, 1 W.	R227LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R263	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.
	R227L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R264	19A700113P41	Composition: 120 ohms ±5%, 1/2 w.
,, 1 w.	R227M	7147161927	Composition: 2.0 ohms ±5%, 1/2 w.	R2 d5	19A700113P55	Composition: 470 ohms ±5%, 1/2 w.
,, 1 w.	R227H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R266	19A700106P63	Composition: 1K ohms ±5%, 1/4 w.
, 1 W.	R228LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R267	19A700106P69	Composition: 1.8K ohms ±5%, 1/4 w.
, 1 W.	R228L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R268	19A700106P15	Composition: 10 ohms ±5%, 1/4 w.
, 1/2 w.	росам	7147161P27	Composition: 2.0 ohms £5%, 1/2 w.	H269	194700113P15	Composition: 10 ohms ±5%, 1/2 w.
1/2 w.	R228M	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R270	3R152P241J	Composition: 240 ohms ±5%, 1/4 w.
, 1/2 w.	R228H	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R271	19A700106P75	Composition: 3.3K ohms ±5%, 1/4 w.
., 1/2 w.	R2291L	19A700113P11	Composition: 3.9 ohms ±5%, 1/2 *.	R272	19A70013P15	Composition: 10 ohms ±5%, 1/2 w.
, 1/2 w.	R229L R229M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R273	3R78P100K	Composition: 10 ohms ±10%, 1 w.
ı, 1/2 w.	R229H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	thru R277	SATOL AVOID	
, 1/2 w.	R230LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	[ ]		VOLTAGE REGULATORS
, 1/2 w.	R230L	19A700113P11	Composition: 3.9 ohms ±5%, 1/2 w.	VR201	4036887P1	Zener: 500 mb, 2.3 v. nominal.
, 1/2 w.	R230L R230M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	VR202	4036887P5	Zener: 500 mm, 5.4 v. nominal.
, 1/2 w.	R230M	7147161P27 7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	I	100000110	
, 1/2 w.		19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.			
, 1/2 w.	R231LL	19A700113P11	Composition: 3.9 ohms ±5%, 1/2 w.	W201	19A129571P1	Strap.
, 1/2 w.	R231L		Composition: 2.0 ohms ±5%, 1/2 w.	n 202	19B219998P2	Jumper.
, 1/2 w.	R231M	7147161P27 7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	n203	19B219998P1	Jumper.
, 1/2 w.	R231H	7147161P22 19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	w204	19C320624P1	Strip, connector.
, 1/2 w.	R232LL		Composition: 3.9 ohms ±5%, 1/2 w.	w205		(Part of printed wiring board 19D417923P1).
. 1/2 w.	R232L R232M	19A700113P5 7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	thru w209		
		7147161P27 7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.			
٠, ١ %.	R232H		Composition: 6.8 ohas ±5%, 1/2 w.			HEAT SINK ASSEMBLY 19B21968866 M MODEL AND INTERMITTANT DUTY STATION
•	R233LL	19A700113P11	Composition: 3.9 ohms ±5%, 1/2 *.			19B219688G18 E MODEL
, 1/2 w.	R233L	19A700113P5	Composition: 2.0 ohms ±5%, 1/2 w.			
i, 1/2 w.	R233M	7147161P27	Composition: 1.2 ohms 15%, 1/2 w.	C297	19A116708P1	Ceramic, feed-thru; 0.01 µf +100% -0%, 500 VDCW;
5, 1/2 w.	R233H	7147161P22	Composition: 6.8 ohms ±5%, 1/2 w.	and C298		sim to Erie Style 327.
i, 1/2 w.	R234LL	19A700113P11 19A700113P5	Composition: 3.9 ohms ±5%, 1/2 *.	C298	19A115680P10	Electrolytic: 200 µf +150% -10%, 18 VDC%; sim
6, 1/2 w.	R234L		Composition: 2.0 ohms ±5%, 1/2 w.			to Mallory Type TTX.
6, 1/2 w.	R234M	7147161P27	Composition: 1.2 ohms 15%, 1/2 w.			DIODES AND RECTIFIERS
6, 1/2 %.	R234H	7147161P22	Composition: 6.8 ohms ±5%, 1/2 w.	CR295	19Al16783Pl	Silicon.
-	R235LL	19A700113P11	Composition: 3.9 ohms £5%, 1/2 w.	CK295	150110103P1	
6, 1/2 w.	R235L	19A700113P5	Composition: 5.5 Onno 10,5 1/4 *-			
	1			1 1	1	

SYMBOL	GE PART NO.	DESCRIPTION
		MISCELLANEOUS
	19A129361P1	Shield. (Located between L246 & L247, L247 & L248).
	19A129361P2	Shield, (Located between L245 & L246),
	19D416275P2	Filter casting.
	19A134016P1	Insulator, bushing. (Used with Q217).
	19A116023P1	Insulator, plate. (Used with Q217).
	19D416712P6	Insulator. (Located under Power Amplifier Board).
	19A129661P1	Insulator. (Located at L298).
<u> </u>	19B201074P312	Tap screw, Phillips POZIDRIV®: No. 6-32 x 3/4. (Secures Filter Casting).
	5492178P2	Washer, spring tension: sim to wallace Barnes 375-20. (Used with Q204-Q209).
	N207P15C6	Hexnut: No. 8-32. (Used with Q204).
	19A129434P1	Washer. (Used with C297, C298).
	N207P16C6	Nut, hex: No. 10-32. (Used with Q205-Q209).

#### **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A Power Amplifier Board 19D417927G1-4
  - To improve operation. Changed CR201.
- REV. B Power Amplifier Board 19D41792761

To improve stopband attenuation (25-30 MHz range) Changed C4201LL and C4206LL.

- REV. B Power Amplifier Board 19D417927G2-4
- REV. C Power Amplifier Board 19D417927G1

To improve operation of power control circuit. Added C4230,

REV. C - Power Amplifier Board 19D417927G2

To improve low pass filter response. Changed C4205L.